



# M95160-x M95080-x

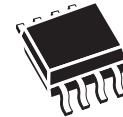
16 Kbit and 8 Kbit serial SPI bus EEPROM  
with high speed clock

## Features

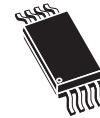
- Compatible with SPI bus serial interface (positive clock SPI modes)
- Single supply voltage:
  - 4.5 V to 5.5 V for M95xxx
  - 2.5 V to 5.5 V for M95xxx-W
  - 1.8 V to 5.5 V for M95xxx-R
  - 1.7 V to 5.5 V for M95xxx-F
- High speed: 10 MHz
- Status Register
- Hardware protection of the Status Register
- Byte and page write (up to 32 bytes)
- Self-timed programming cycle
- Adjustable size read-only EEPROM area
- Enhanced ESD protection
- More than 1 million write cycles
- More than 40-year data retention
- Packages
  - ECOPACK® (RoHS compliant)

**Table 1. Device summary**

| Reference | Part number |
|-----------|-------------|
| M95160-x  | M95160      |
|           | M95160-W    |
|           | M95160-R    |
|           | M95160-F    |
| M95080-x  | M95080      |
|           | M95080-W    |
|           | M95080-R    |



SO8 (MN)  
150 mil width



TSSOP8 (DW)  
169 mil width



UFDFPN8 (MB)  
2 x 3 mm (MLP)



WLCSP (CS)<sup>1)</sup>

1. Preliminary data.

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# 1 Description

The M95160-x and M95080-x are electrically erasable programmable memory (EEPROM) devices. They are accessed by a high-speed SPI-compatible bus. The memory array is organized as 2048 x 8 bit (M95160-x), and 1024 x 8 bit (M95080-x).

The device is accessed by a simple serial interface that is SPI-compatible. The bus signals are C, D and Q, as shown in [Table 2](#) and [Figure 1](#).

The device is selected when Chip Select ( $\overline{S}$ ) is taken low. Communications with the device can be interrupted using Hold ( $\overline{HOLD}$ ).

Figure 1. Logic diagram

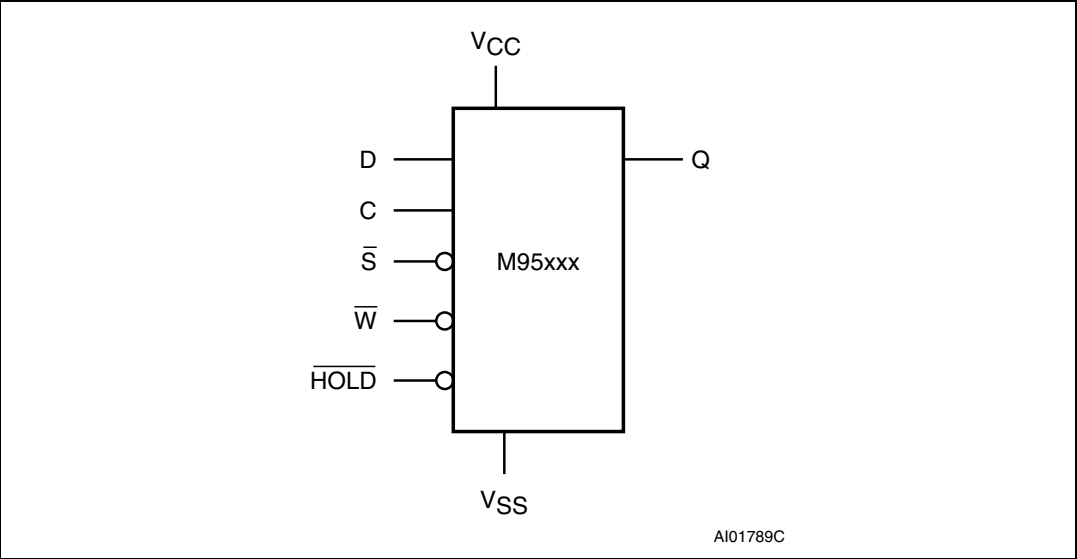
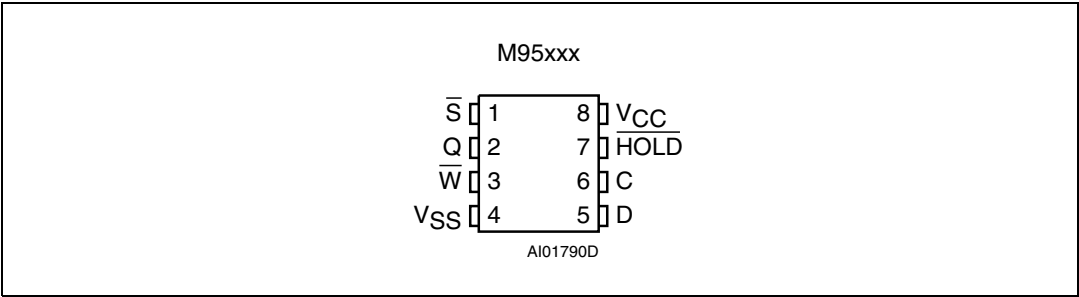


Table 2. Signal names

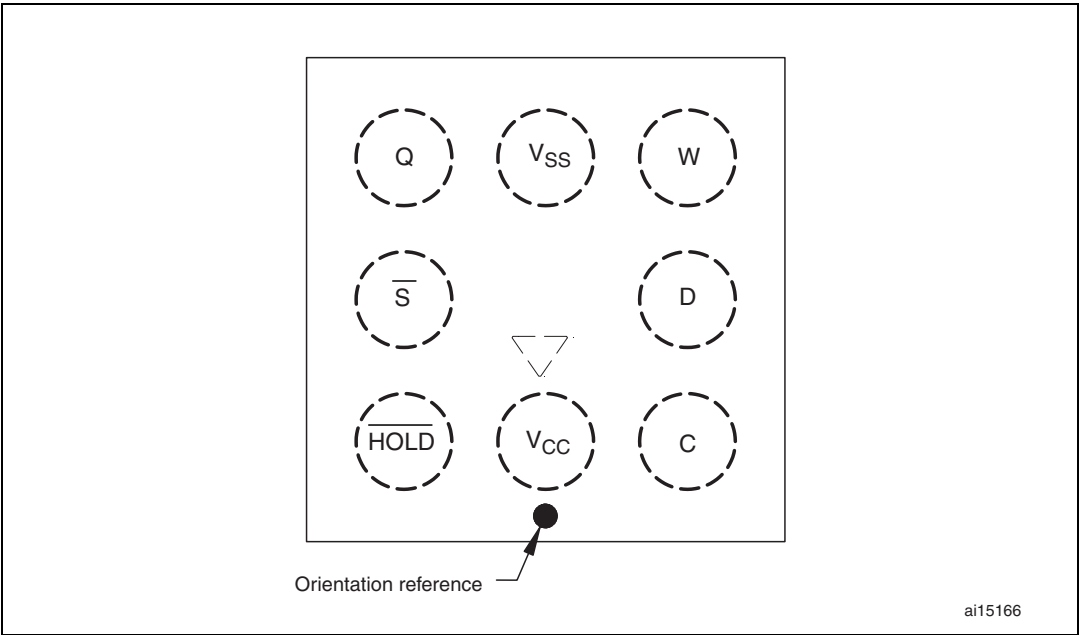
| Signal name       | Function           | Direction |
|-------------------|--------------------|-----------|
| C                 | Serial Clock       | Input     |
| D                 | Serial Data input  | Input     |
| Q                 | Serial Data output | Output    |
| $\overline{S}$    | Chip Select        | Input     |
| $\overline{W}$    | Write Protect      | Input     |
| $\overline{HOLD}$ | Hold               | Input     |
| V <sub>CC</sub>   | Supply voltage     |           |
| V <sub>SS</sub>   | Ground             |           |

Figure 2. 8-pin package connections (top view)



1. See [Package mechanical data](#) section for package dimensions, and how to identify pin-1.

Figure 3. M95160 WLCSP connections (top view, marking side, with balls on the underside)



## 2 Signal description

During all operations,  $V_{CC}$  must be held stable and within the specified valid range:  $V_{CC}(\min)$  to  $V_{CC}(\max)$ .

All of the input and output signals must be held high or low (according to voltages of  $V_{IH}$ ,  $V_{OH}$ ,  $V_{IL}$  or  $V_{OL}$ , as specified in [Table 14.](#) to [Table 19.](#)). These signals are described next.

### 2.1 Serial Data output (Q)

This output signal is used to transfer data serially out of the device. Data is shifted out on the falling edge of Serial Clock (C).

### 2.2 Serial Data input (D)

This input signal is used to transfer data serially into the device. It receives instructions, addresses, and the data to be written. Values are latched on the rising edge of Serial Clock (C).

### 2.3 Serial Clock (C)

This input signal provides the timing of the serial interface. Instructions, addresses, or data present at Serial Data Input (D) are latched on the rising edge of Serial Clock (C). Data on Serial Data Output (Q) changes after the falling edge of Serial Clock (C).

### 2.4 Chip Select ( $\overline{S}$ )

When this input signal is high, the device is deselected and Serial Data Output (Q) is at high impedance. Unless an internal Write cycle is in progress, the device will be in the Standby Power mode. Driving Chip Select ( $\overline{S}$ ) low selects the device, placing it in the Active Power mode.

After Power-up, a falling edge on Chip Select ( $\overline{S}$ ) is required prior to the start of any instruction.

### 2.5 Hold ( $\overline{HOLD}$ )

The Hold ( $\overline{HOLD}$ ) signal is used to pause any serial communications with the device without deselecting the device.

During the Hold condition, the Serial Data Output (Q) is high impedance, and Serial Data Input (D) and Serial Clock (C) are Don't Care.

To start the Hold condition, the device must be selected, with Chip Select ( $\overline{S}$ ) driven low.

## 2.6 Write Protect ( $\overline{W}$ )

The main purpose of this input signal is to freeze the size of the area of memory that is protected against Write instructions (as specified by the values in the BP1 and BP0 bits of the Status Register).

This pin must be driven either high or low, and must be stable during all write instructions.

## 2.7 $V_{CC}$ supply voltage

$V_{CC}$  is the supply voltage.

## 2.8 $V_{SS}$ ground

$V_{SS}$  is the reference for the  $V_{CC}$  supply voltage.



### 3.1 SPI modes

These devices can be driven by a microcontroller with its SPI peripheral running in either of the two following modes:

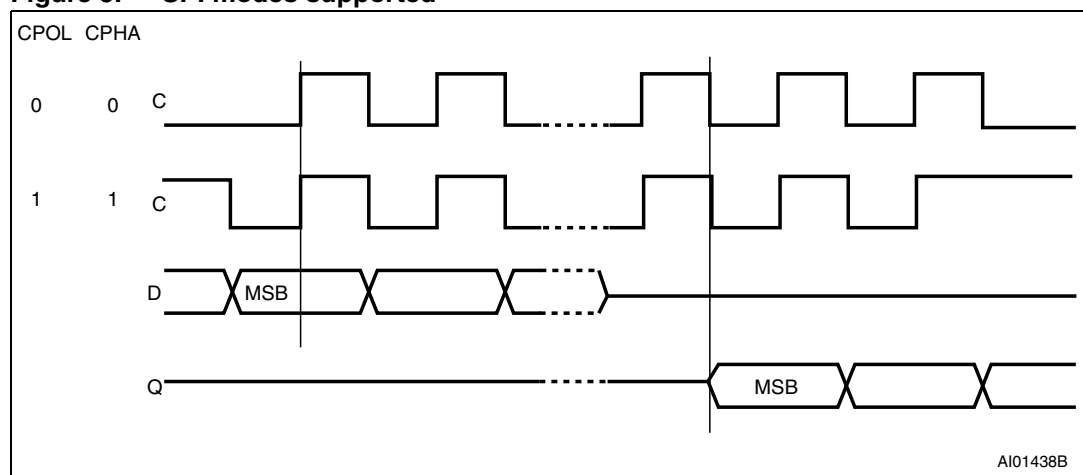
- CPOL=0, CPHA=0
- CPOL=1, CPHA=1

For these two modes, input data is latched in on the rising edge of Serial Clock (C), and output data is available from the falling edge of Serial Clock (C).

The difference between the two modes, as shown in [Figure 5](#), is the clock polarity when the bus master is in Stand-by mode and not transferring data:

- C remains at 0 for (CPOL=0, CPHA=0)
- C remains at 1 for (CPOL=1, CPHA=1)

**Figure 5. SPI modes supported**



## 4 Operating features

### 4.1 Supply voltage ( $V_{CC}$ )

#### 4.1.1 Operating supply voltage $V_{CC}$

Prior to selecting the memory and issuing instructions to it, a valid and stable  $V_{CC}$  voltage within the specified [ $V_{CC}(\min)$ ,  $V_{CC}(\max)$ ] range must be applied (see [Table 9](#), [Table 10](#) and [Table 11](#)). This voltage must remain stable and valid until the end of the transmission of the instruction and, for a Write instruction, until the completion of the internal write cycle ( $t_W$ ). In order to secure a stable DC supply voltage, it is recommended to decouple the  $V_{CC}$  line with a suitable capacitor (usually of the order of 10 nF to 100 nF) close to the  $V_{CC}/V_{SS}$  package pins.

#### 4.1.2 Device reset

In order to prevent inadvertent write operations during power-up, a power-on-reset (POR) circuit is included. At power-up, the device does not respond to any instruction until  $V_{CC}$  reaches the POR threshold voltage (this threshold is defined in DC characteristics tables [15](#), [16](#), [17](#), [18](#), [19](#) and [20](#) as  $V_{RES}$ ).

When  $V_{CC}$  passes over the POR threshold, the device is reset and is in the following state:

- in Standby Power mode
- deselected (note that, to be executed, an instruction must be preceded by a falling edge on Chip Select ( $\overline{S}$ ))
- Status Register value:
  - the Write Enable Latch (WEL) is reset to 0
  - Write In Progress (WIP) is reset to 0
  - The SRWD, BP1 and BP0 bits remain unchanged (non-volatile bits)

When  $V_{CC}$  passes over the POR threshold, the device is reset and enters the Standby Power mode. The device must not be accessed until  $V_{CC}$  reaches a valid and stable  $V_{CC}$  voltage within the specified [ $V_{CC}(\min)$ ,  $V_{CC}(\max)$ ] range defined in [Table 9](#), [Table 10](#) and [Table 11](#).

#### 4.1.3 Power-up conditions

When the power supply is turned on,  $V_{CC}$  rises continuously from  $V_{SS}$  to  $V_{CC}$ . During this time, the Chip Select ( $\overline{S}$ ) line is not allowed to float but should follow the  $V_{CC}$  voltage. It is therefore recommended to connect the  $\overline{S}$  line to  $V_{CC}$  via a suitable pull-up resistor (see [Figure 4](#)).

In addition, the Chip Select ( $\overline{S}$ ) input offers a built-in safety feature, as the  $\overline{S}$  input is edge sensitive as well as level sensitive: after power-up, the device does not become selected until a falling edge has first been detected on Chip Select ( $\overline{S}$ ). This ensures that Chip Select ( $\overline{S}$ ) must have been high, prior to going low to start the first operation.

The  $V_{CC}$  voltage has to rise continuously from 0 V up to the minimum  $V_{CC}$  operating voltage defined in [Table 9](#), [Table 10](#) and [Table 11](#) and the rise time must not vary faster than 1 V/ $\mu$ s.

#### 4.1.4 Power-down

During power-down (continuous decrease in the  $V_{CC}$  supply voltage below the minimum  $V_{CC}$  operating voltage defined in [Table 9](#), [Table 10](#) and [Table 11](#)), the device must be:

- deselected (Chip Select  $\overline{S}$  should be allowed to follow the voltage applied on  $V_{CC}$ )
- in Standby Power mode (there should not be any internal write cycle in progress).

## 4.2 Active Power and Standby Power modes

When Chip Select ( $\overline{S}$ ) is low, the device is selected, and in the Active Power mode. The device consumes  $I_{CC}$ , as specified in [Table 14](#). to [Table 19](#).

When Chip Select ( $\overline{S}$ ) is high, the device is deselected. If a Write cycle is not currently in progress, the device then goes into the Standby Power mode, and the device consumption drops to  $I_{CC1}$ .

## 4.3 Hold condition

The Hold ( $\overline{HOLD}$ ) signal is used to pause any serial communications with the device without resetting the clocking sequence.

During the Hold condition, the Serial Data Output (Q) is high impedance, and Serial Data Input (D) and Serial Clock (C) are Don't Care.

To enter the Hold condition, the device must be selected, with Chip Select ( $\overline{S}$ ) low.

Normally, the device is kept selected, for the whole duration of the Hold condition.

Deselecting the device while it is in the Hold condition, has the effect of resetting the state of the device, and this mechanism can be used if it is required to reset any processes that had been in progress.

The Hold condition starts when the Hold ( $\overline{HOLD}$ ) signal is driven low at the same time as Serial Clock (C) already being low.

The Hold condition ends when the Hold ( $\overline{HOLD}$ ) signal is driven high at the same time as Serial Clock (C) already being low.

## 4.4 Status Register

[Figure 6](#). shows the position of the Status Register in the control logic of the device. The Status Register contains a number of status and control bits that can be read or set (as appropriate) by specific instructions. See [Section 6.3: Read Status Register \(RDSR\)](#) for a detailed description of the Status Register bits

## 4.5 Data protection and protocol control

Non-volatile memory devices can be used in environments that are particularly noisy, and within applications that could experience problems if memory bytes are corrupted. Consequently, the device features the following data protection mechanisms:

- Write and Write Status Register instructions are checked that they consist of a number of clock pulses that is a multiple of eight, before they are accepted for execution.
- All instructions that modify data must be preceded by a Write Enable (WREN) instruction to set the Write Enable Latch (WEL) bit. This bit is returned to its reset state by the following events:
  - Power-up
  - Write Disable (WRDI) instruction completion
  - Write Status Register (WRSR) instruction completion
  - Write (WRITE) instruction completion
- The Block Protect (BP1, BP0) bits in the Status Register allow part of the memory to be configured as read-only.
- The Write Protect ( $\overline{W}$ ) signal allows the Block Protect (BP1, BP0) bits of the Status Register to be protected.

For any instruction to be accepted, and executed, Chip Select ( $\overline{S}$ ) must be driven high after the rising edge of Serial Clock (C) for the last bit of the instruction, and before the next rising edge of Serial Clock (C).

Two points need to be noted in the previous sentence:

- The 'last bit of the instruction' can be the eighth bit of the instruction code, or the eighth bit of a data byte, depending on the instruction (except for Read Status Register (RDSR) and Read (READ) instructions).
- The 'next rising edge of Serial Clock (C)' might (or might not) be the next bus transaction for some other device on the SPI bus.

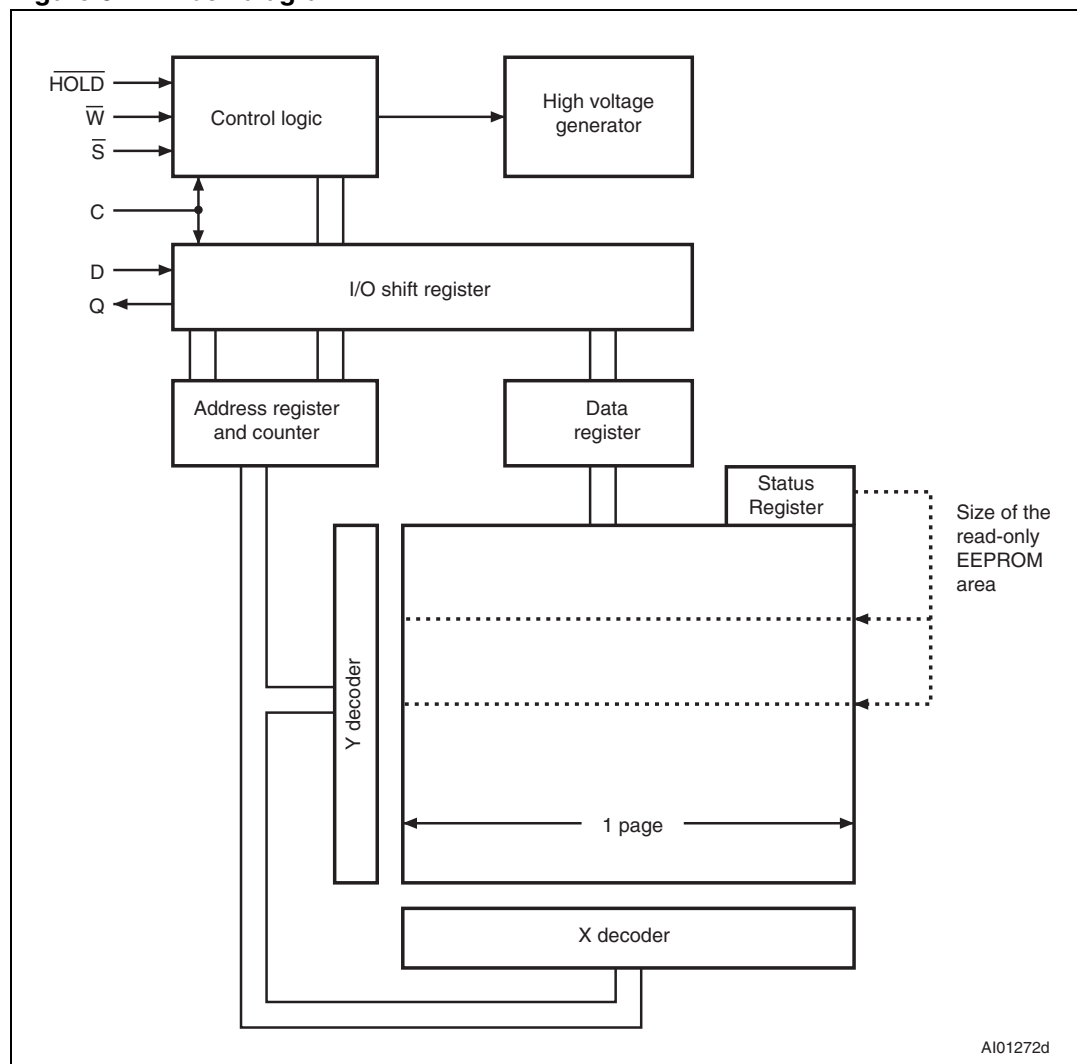
**Table 3. Write-protected block size**

| Status Register bits |     | Protected block | Protected array addresses |               |
|----------------------|-----|-----------------|---------------------------|---------------|
| BP1                  | BP0 |                 | M95160-x                  | M95080-x      |
| 0                    | 0   | none            | none                      | none          |
| 0                    | 1   | Upper quarter   | 0600h - 07FFh             | 0300h - 03FFh |
| 1                    | 0   | Upper half      | 0400h - 07FFh             | 0200h - 03FFh |
| 1                    | 1   | Whole memory    | 0000h - 07FFh             | 0000h - 03FFh |

## 5 Memory organization

The memory is organized as shown in [Figure 6](#).

**Figure 6. Block diagram**



# 6 Instructions

Each instruction starts with a single-byte code, as summarized in [Table 4](#).  
If an invalid instruction is sent (one not contained in [Table 4](#)), the device automatically deselects itself.

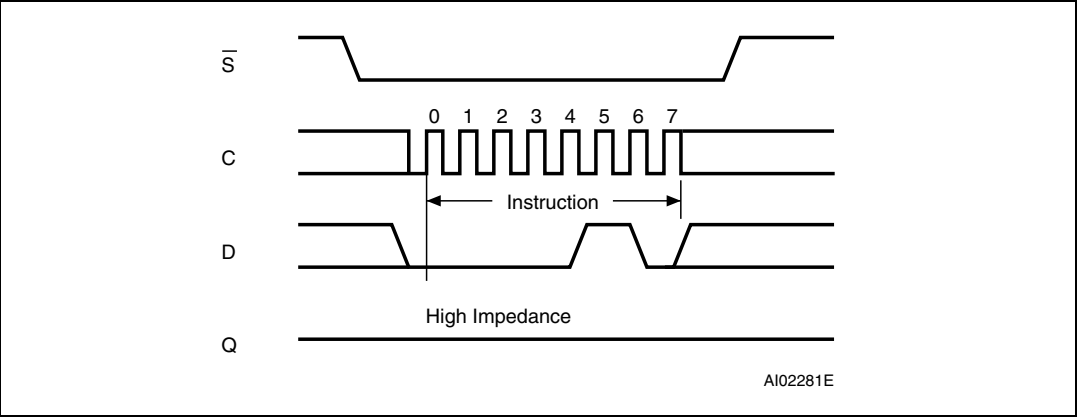
**Table 4. Instruction set**

| Instruction | Description            | Instruction format |
|-------------|------------------------|--------------------|
| WREN        | Write Enable           | 0000 0110          |
| WRDI        | Write Disable          | 0000 0100          |
| RDSR        | Read Status Register   | 0000 0101          |
| WRSR        | Write Status Register  | 0000 0001          |
| READ        | Read from Memory Array | 0000 0011          |
| WRITE       | Write to Memory Array  | 0000 0010          |

## 6.1 Write Enable (WREN)

The Write Enable Latch (WEL) bit must be set prior to each WRITE and WRSR instruction. The only way to do this is to send a Write Enable instruction to the device.  
As shown in [Figure 7](#), to send this instruction to the device, Chip Select ( $\overline{S}$ ) is driven low, and the bits of the instruction byte are shifted in, on Serial Data Input (D). The device then enters a wait state. It waits for the device to be deselected, by Chip Select ( $\overline{S}$ ) being driven high.

**Figure 7. Write Enable (WREN) sequence**



## 6.2 Write Disable (WRDI)

One way of resetting the Write Enable Latch (WEL) bit is to send a Write Disable instruction to the device.

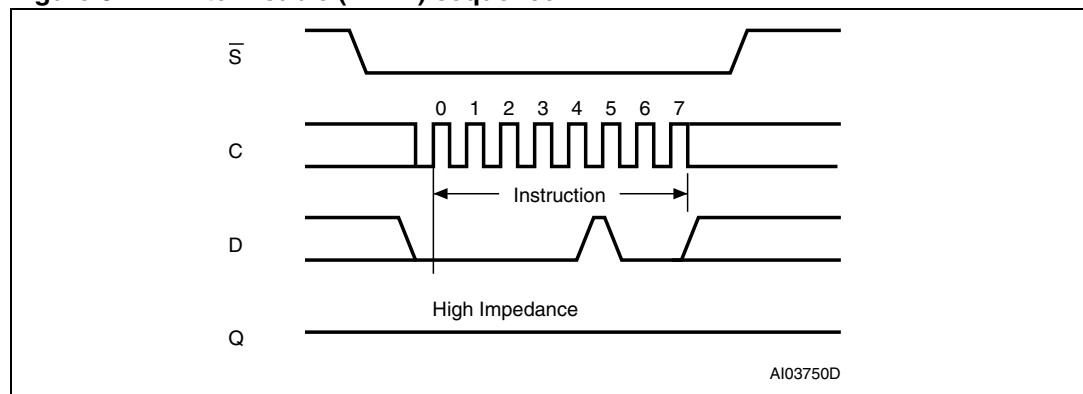
As shown in [Figure 8](#), to send this instruction to the device, Chip Select ( $\overline{S}$ ) is driven low, and the bits of the instruction byte are shifted in, on Serial Data Input (D).

The device then enters a wait state. It waits for the device to be deselected, by Chip Select ( $\overline{S}$ ) being driven high.

The Write Enable Latch (WEL) bit, in fact, becomes reset by any of the following events:

- Power-up
- WRDI instruction execution
- WRSR instruction completion
- WRITE instruction completion.

**Figure 8. Write Disable (WRDI) sequence**



## 6.3 Read Status Register (RDSR)

The Read Status Register (RDSR) instruction allows the Status Register to be read. The Status Register may be read at any time, even while a Write or Write Status Register cycle is in progress. When one of these cycles is in progress, it is recommended to check the Write In Progress (WIP) bit before sending a new instruction to the device. It is also possible to read the Status Register continuously, as shown in [Figure 9](#).

The status and control bits of the Status Register are as follows:

### 6.3.1 WIP bit

The Write In Progress (WIP) bit indicates whether the memory is busy with a Write or Write Status Register cycle. When set to 1, such a cycle is in progress, when reset to 0 no such cycle is in progress.

### 6.3.2 WEL bit

The Write Enable Latch (WEL) bit indicates the status of the internal Write Enable Latch. When set to 1 the internal Write Enable Latch is set, when set to 0 the internal Write Enable Latch is reset and no Write or Write Status Register instruction is accepted.

### 6.3.3 BP1, BP0 bits

The Block Protect (BP1, BP0) bits are non-volatile. They define the size of the area to be software protected against Write instructions. These bits are written with the Write Status Register (WRSR) instruction. When one or both of the Block Protect (BP1, BP0) bits is set to 1, the relevant memory area (as defined in [Table 5](#)) becomes protected against Write (WRITE) instructions. The Block Protect (BP1, BP0) bits can be written provided that the Hardware Protected mode has not been set.

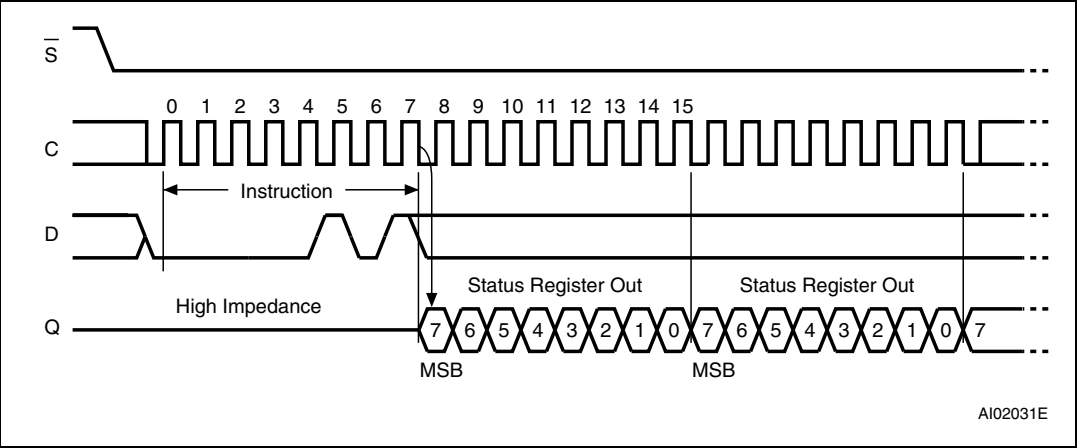
### 6.3.4 SRWD bit

The Status Register Write Disable (SRWD) bit is operated in conjunction with the Write Protect ( $\overline{W}$ ) signal. The Status Register Write Disable (SRWD) bit and Write Protect ( $\overline{W}$ ) signal allow the device to be put in the Hardware Protected mode (when the Status Register Write Disable (SRWD) bit is set to 1, and Write Protect ( $\overline{W}$ ) is driven low). In this mode, the non-volatile bits of the Status Register (SRWD, BP1, BP0) become read-only bits and the Write Status Register (WRSR) instruction is no longer accepted for execution.

**Table 5. Status Register format**

| b7                            |   |   |   | b0                 |     |                        |                       |
|-------------------------------|---|---|---|--------------------|-----|------------------------|-----------------------|
| SRWD                          | 0 | 0 | 0 | BP1                | BP0 | WEL                    | WIP                   |
| Status Register Write Protect |   |   |   | Block Protect Bits |     | Write Enable Latch Bit | Write In Progress Bit |

Figure 9. Read Status Register (RDSR) sequence



## 6.4 Write Status Register (WRSR)

The Write Status Register (WRSR) instruction allows new values to be written to the Status Register. Before it can be accepted, a Write Enable (WREN) instruction must previously have been executed.

The Write Status Register (WRSR) instruction is entered by driving Chip Select ( $\overline{S}$ ) low, followed by the instruction code, the data byte on Serial Data input (D) and Chip Select ( $\overline{S}$ ) driven high. Chip Select ( $\overline{S}$ ) must be driven high after the rising edge of Serial Clock (C) that latches in the eighth bit of the data byte, and before the next rising edge of Serial Clock (C). Otherwise, the Write Status Register (WRSR) instruction is not executed.

The instruction sequence is shown in [Figure 10](#).

Driving the Chip Select ( $\overline{S}$ ) signal high at a byte boundary of the input data triggers the self-timed write cycle that takes  $t_W$  to complete (as specified in [Table 21](#), [Table 22](#), [Table 23](#), [Table 24](#), [Table 26](#) and [Table 27](#)).

While the Write Status Register cycle is in progress, the Status Register may still be read to check the value of the Write in progress (WIP) bit: the WIP bit is 1 during the self-timed write cycle  $t_W$ , and, 0 when the write cycle is complete. The WEL bit (Write enable latch) is also reset at the end of the write cycle  $t_W$ .

The Write Status Register (WRSR) instruction allows the user to change the values of the BP1, BP0 and SRWD bits:

- The Block Protect (BP1, BP0) bits define the size of the area that is to be treated as read only, as defined in [Table 3](#).
- The SRWD bit (Status Register Write Disable bit), in accordance with the signal read on the Write Protect pin ( $\overline{W}$ ), allows the user to set or reset the Write protection mode of the Status Register itself, as defined in [Table 6](#). When in Write-protected mode, the Write Status Register (WRSR) instruction is not executed.

The contents of the SRWD and BP1, BP0 bits are updated after the completion of the WRSR instruction, including the  $t_W$  Write cycle.

The Write Status Register (WRSR) instruction has no effect on the b6, b5, b4, b1, b0 bits in the Status Register. Bits b6, b5, b4 are always read as 0.

**Table 6. Protection modes**

| $\overline{W}$ signal | SRWD bit | Mode                     | Write protection of the Status Register                                                                                        | Memory content                |                                    |
|-----------------------|----------|--------------------------|--------------------------------------------------------------------------------------------------------------------------------|-------------------------------|------------------------------------|
|                       |          |                          |                                                                                                                                | Protected area <sup>(1)</sup> | Unprotected area <sup>(1)</sup>    |
| 1                     | 0        | Software-protected (SPM) | Status Register is writable (if the WREN instruction has set the WEL bit)<br>The values in the BP1 and BP0 bits can be changed | Write-protected               | Ready to accept Write instructions |
| 0                     | 0        |                          |                                                                                                                                |                               |                                    |
| 1                     | 1        | Hardware-protected (HPM) | Status Register is Hardware write-protected<br>The values in the BP1 and BP0 bits cannot be changed                            | Write-protected               | Ready to accept Write instructions |
| 0                     | 1        |                          |                                                                                                                                |                               |                                    |

1. As defined by the values in the Block Protect (BP1, BP0) bits of the Status Register, as shown in [Table 3](#).

The protection features of the device are summarized in [Table 6](#).

When the Status Register Write Disable (SRWD) bit in the Status Register is 0 (its initial delivery state), it is possible to write to the Status Register (provided that the WEL bit has previously been set by a WREN instruction), regardless of the logic level applied on the Write Protect ( $\overline{W}$ ) input pin.

When the Status Register Write Disable (SRWD) bit in the Status Register is set to 1, two cases need to be considered, depending on the state of the Write Protect ( $\overline{W}$ ) input pin:

- If Write Protect ( $\overline{W}$ ) is driven high, it is possible to write to the Status Register (provided that the WEL bit has previously been set by a WREN instruction).
- If Write Protect ( $\overline{W}$ ) is driven low, it is not possible to write to the Status Register even if the WEL bit has previously been set by a WREN instruction. (Attempts to write to the Status Register are rejected, and are not accepted for execution). As a consequence, all the data bytes in the memory area, which are software-protected (SPM) by the Block Protect (BP1, BP0) bits in the Status Register, are also hardware-protected against data modification.

Regardless of the order of the two events, the Hardware-protected mode (HPM) can be entered by:

- either setting the SRWD bit after driving the Write Protect ( $\overline{W}$ ) input pin low
- or driving the Write Protect ( $\overline{W}$ ) input pin low after setting the SRWD bit

Once the Hardware-protected mode (HPM) has been entered, the only way of exiting it is to pull high the Write Protect ( $\overline{W}$ ) input pin.

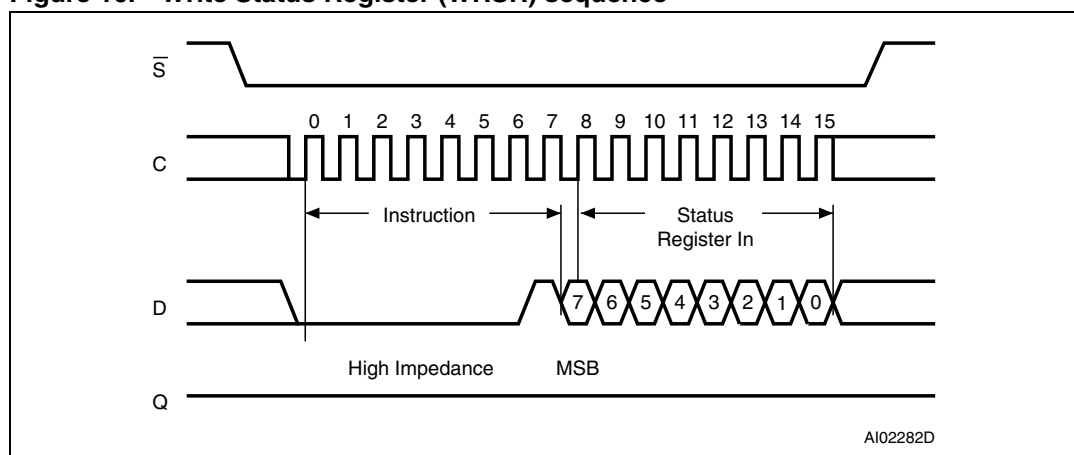
If the Write Protect ( $\overline{W}$ ) input pin is permanently tied high, the Hardware-protected mode (HPM) can never be activated, and only the Software-protected mode (SPM), using the Block Protect (BP1, BP0) bits in the Status Register, can be used.

**Table 7. Address range bits<sup>(1)</sup>**

| Device       | M95160-x | M95080-x |
|--------------|----------|----------|
| Address bits | A10-A0   | A9-A0    |

1. b15 to b11 are Don't Care on the M95160-x.  
b15 to b10 are Don't Care on the M95080-x.

**Figure 10. Write Status Register (WRSR) sequence**



## 6.5 Read from Memory Array (READ)

As shown in [Figure 11.](#), to send this instruction to the device, Chip Select ( $\overline{S}$ ) is first driven low. The bits of the instruction byte and address bytes are then shifted in, on Serial Data Input (D). The address is loaded into an internal address register, and the byte of data at that address is shifted out, on Serial Data Output (Q).

If Chip Select ( $\overline{S}$ ) continues to be driven low, the internal address register is automatically incremented, and the byte of data at the new address is shifted out.

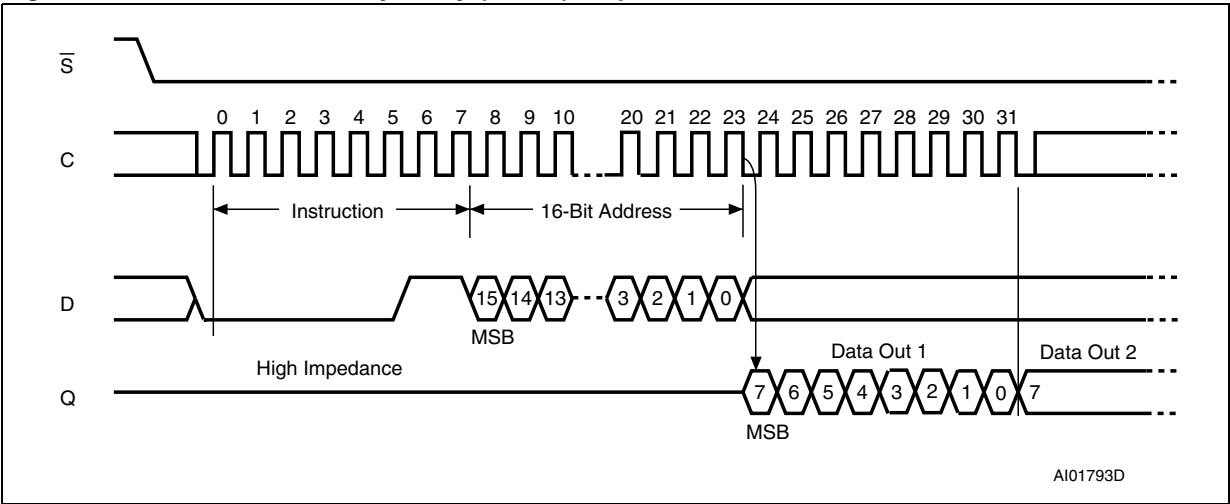
When the highest address is reached, the address counter rolls over to zero, allowing the Read cycle to be continued indefinitely. The whole memory can, therefore, be read with a single READ instruction.

The Read cycle is terminated by driving Chip Select ( $\overline{S}$ ) high. The rising edge of the Chip Select ( $\overline{S}$ ) signal can occur at any time during the cycle.

The first byte addressed can be any byte within any page.

The instruction is not accepted, and is not executed, if a Write cycle is currently in progress.

**Figure 11. Read from Memory Array (READ) sequence**



1. Depending on the memory size, as shown in [Table 7.](#), the most significant address bits are Don't Care.

## 6.6 Write to Memory Array (WRITE)

As shown in [Figure 12.](#), to send this instruction to the device, Chip Select ( $\overline{S}$ ) is first driven low. The bits of the instruction byte, address byte, and at least one data byte are then shifted in, on Serial Data Input (D).

The instruction is terminated by driving Chip Select ( $\overline{S}$ ) high at a byte boundary of the input data. The self-timed Write cycle, triggered by the Chip Select ( $\overline{S}$ ) rising edge, continues for a period  $t_W$  (as specified in [Table 22.](#) to [Table 26.](#)), at the end of which the Write in Progress (WIP) bit is reset to 0.

In the case of [Figure 12.](#), Chip Select ( $\overline{S}$ ) is driven high after the eighth bit of the data byte has been latched in, indicating that the instruction is being used to write a single byte. If, though, Chip Select ( $\overline{S}$ ) continues to be driven low, as shown in [Figure 13.](#), the next byte of input data is shifted in, so that more than a single byte, starting from the given address towards the end of the same page, can be written in a single internal Write cycle.

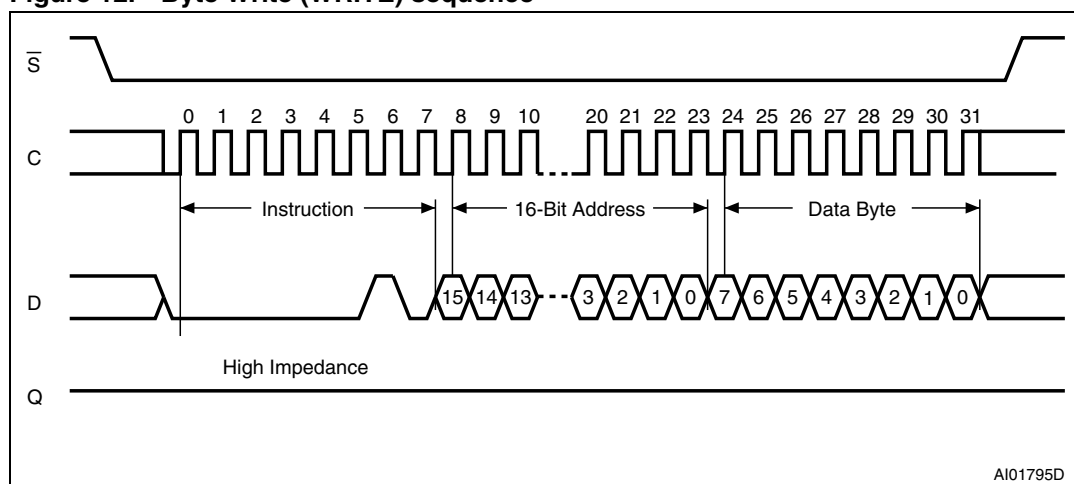
Each time a new data byte is shifted in, the least significant bits of the internal address counter are incremented. If the number of data bytes sent to the device exceeds the page boundary, the internal address counter rolls over to the beginning of the page, and the previous data there are overwritten with the incoming data. (The page size of these devices is 32 bytes).

The instruction is not accepted, and is not executed, under the following conditions:

- if the Write Enable Latch (WEL) bit has not been set to 1 (by executing a Write Enable instruction just before)
- if a Write cycle is already in progress
- if the device has not been deselected, by Chip Select ( $\overline{S}$ ) being driven high, at a byte boundary (after the eighth bit, b0, of the last data byte that has been latched in)
- if the addressed page is in the region protected by the Block Protect (BP1 and BP0) bits.

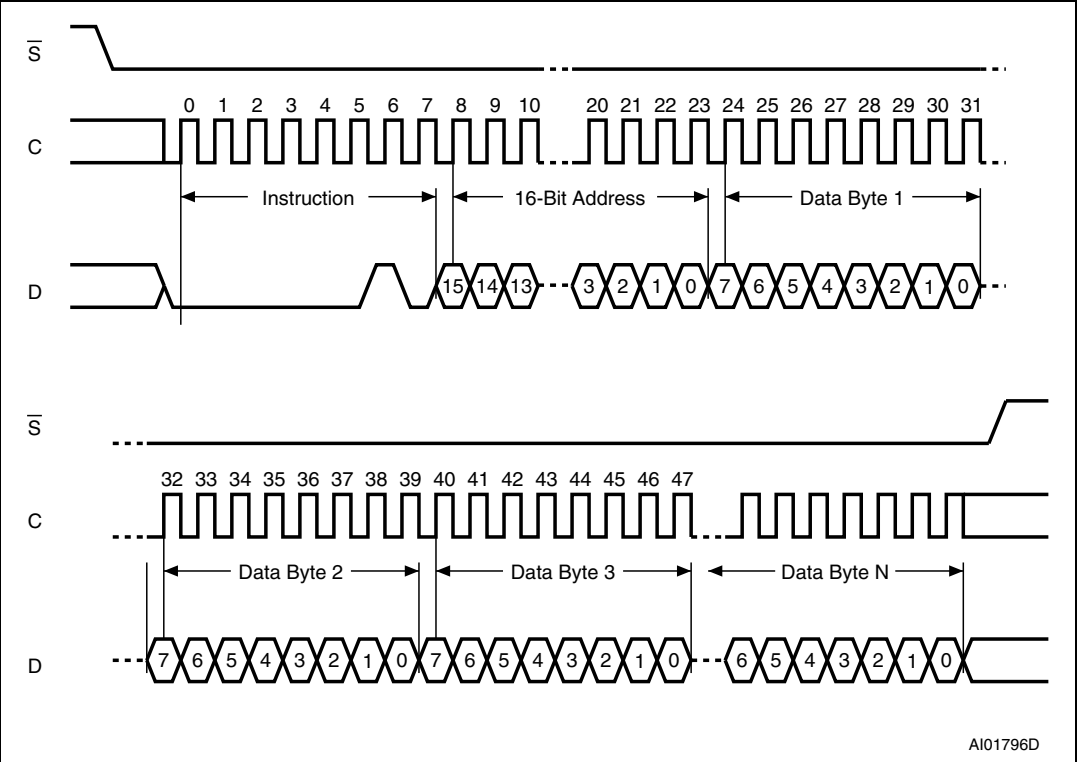
**Note:** The self-timed write cycle  $t_W$  is internally executed as a sequence of two consecutive events: [Erase addressed byte(s)], followed by [Program addressed byte(s)]. An erased bit is read as "0" and a programmed bit is read as "1".

**Figure 12. Byte Write (WRITE) sequence**



1. Depending on the memory size, as shown in [Table 7.](#), the most significant address bits are Don't Care.

Figure 13. Page Write (WRITE) sequence



1. Depending on the memory size, as shown in [Table 7.](#), the most significant address bits are Don't Care.

## 7 Delivery state

### 7.1 Initial delivery state

The device is delivered with the memory array set at all 1s (FFh). The Status Register Write Disable (SRWD) and Block Protect (BP1 and BP0) bits are initialized to 0.

## 8 Maximum rating

Stressing the device outside the ratings listed in [Table 8](#), may cause permanent damage to the device. These are stress ratings only, and operation of the device at these, or any other conditions outside those indicated in the operating sections of this specification, is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

**Table 8. Absolute maximum ratings**

| Symbol     | Parameter                                                         | Min.                    | Max.         | Unit |
|------------|-------------------------------------------------------------------|-------------------------|--------------|------|
| $T_A$      | Ambient operating temperature                                     | −40                     | 130          | °C   |
| $T_{STG}$  | Storage temperature                                               | −65                     | 150          | °C   |
| $T_{LEAD}$ | Lead temperature during soldering                                 | See note <sup>(1)</sup> |              | °C   |
| $V_O$      | Output voltage                                                    | −0.50                   | $V_{CC}+0.6$ | V    |
| $V_I$      | Input voltage                                                     | −0.50                   | 6.5          | V    |
| $V_{CC}$   | Supply voltage                                                    | −0.50                   | 6.5          | V    |
| $V_{ESD}$  | Electrostatic discharge voltage (human body model) <sup>(2)</sup> | −4000                   | 4000         | V    |

1. Compliant with JEDEC Std J-STD-020C (for small body, Sn-Pb or Pb assembly), the ST ECOPACK<sup>®</sup> 7191395 specification, and the European directive on Restrictions on Hazardous Substances (RoHS) 2002/95/EU

2. AEC-Q100-002 (compliant with JEDEC Std JESD22-A114, C1=100 pF, R1=1500  $\Omega$ , R2=500  $\Omega$ )

## 9 DC and AC parameters

This section summarizes the operating and measurement conditions, and the DC and AC characteristics of the device. The parameters in the DC and AC characteristic tables that follow are derived from tests performed under the measurement conditions summarized in the relevant tables. Designers should check that the operating conditions in their circuit match the measurement conditions when relying on the quoted parameters.

**Table 9. Operating conditions (M95160 and M95080)**

| Symbol   | Parameter                                      | Min. | Max. | Unit |
|----------|------------------------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                                 | 4.5  | 5.5  | V    |
| $T_A$    | Ambient operating temperature (device grade 6) | -40  | 85   | °C   |
|          | Ambient operating temperature (device grade 3) | -40  | 125  | °C   |

**Table 10. Operating conditions (M95160-W and M95080-W)**

| Symbol   | Parameter                                      | Min. | Max. | Unit |
|----------|------------------------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                                 | 2.5  | 5.5  | V    |
| $T_A$    | Ambient operating temperature (device grade 6) | -40  | 85   | °C   |
|          | Ambient operating temperature (device grade 3) | -40  | 125  | °C   |

**Table 11. Operating conditions (M95160-R and M95080-R)**

| Symbol   | Parameter                     | Min. | Max. | Unit |
|----------|-------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                | 1.8  | 5.5  | V    |
| $T_A$    | Ambient operating temperature | -40  | 85   | °C   |

**Table 12. Operating conditions (M95160-F)<sup>(1)</sup>**

| Symbol   | Parameter                     | Min. | Max. | Unit |
|----------|-------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                | 1.7  | 5.5  | V    |
| $T_A$    | Ambient operating temperature | -40  | 85   | °C   |

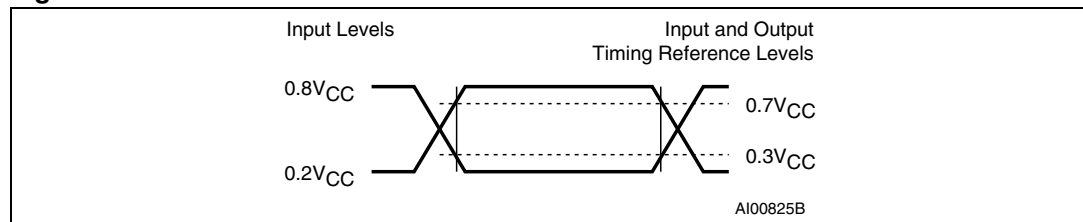
1. Preliminary data.

**Table 13. AC measurement conditions<sup>(1)</sup>**

| Symbol | Parameter                                  | Min.                                     | Typ. | Max. | Unit |
|--------|--------------------------------------------|------------------------------------------|------|------|------|
| $C_L$  | Load capacitance                           |                                          | 30   |      | pF   |
|        | Input rise and fall times                  |                                          |      | 50   | ns   |
|        | Input pulse voltages                       | 0.2V <sub>CC</sub> to 0.8V <sub>CC</sub> |      |      | V    |
|        | Input and output timing reference voltages | 0.3V <sub>CC</sub> to 0.7V <sub>CC</sub> |      |      | V    |

1. Output Hi-Z is defined as the point where data out is no longer driven.

Figure 14. AC measurement I/O waveform

Table 14. Capacitance<sup>(1)</sup>

| Symbol           | Parameter                      | Test condition         | Min. | Max. | Unit |
|------------------|--------------------------------|------------------------|------|------|------|
| C <sub>OUT</sub> | Output capacitance (Q)         | V <sub>OUT</sub> = 0 V |      | 8    | pF   |
| C <sub>IN</sub>  | Input capacitance (D)          | V <sub>IN</sub> = 0 V  |      | 8    | pF   |
|                  | Input capacitance (other pins) | V <sub>IN</sub> = 0 V  |      | 6    | pF   |

1. Sampled only, not 100% tested, at T<sub>A</sub> = 25 °C and a frequency of 5 MHz.

Table 15. DC characteristics (M95160 and M95080, device grade 3)

| Symbol                          | Parameter                        | Test condition                                                                                                 | Min.                | Max.                | Unit |
|---------------------------------|----------------------------------|----------------------------------------------------------------------------------------------------------------|---------------------|---------------------|------|
| I <sub>LI</sub>                 | Input leakage current            | V <sub>IN</sub> = V <sub>SS</sub> or V <sub>CC</sub>                                                           |                     | ± 2                 | μA   |
| I <sub>LO</sub>                 | Output leakage current           | $\overline{S}$ = V <sub>CC</sub> , V <sub>OUT</sub> = V <sub>SS</sub> or V <sub>CC</sub>                       |                     | ± 2                 | μA   |
| I <sub>CC</sub>                 | Supply current                   | C = 0.1V <sub>CC</sub> /0.9V <sub>CC</sub> at 5 MHz, V <sub>CC</sub> = 5 V, Q = open                           |                     | 3                   | mA   |
| I <sub>CC1</sub>                | Supply current (Standby)         | $\overline{S}$ = V <sub>CC</sub> , V <sub>CC</sub> = 5 V, V <sub>IN</sub> = V <sub>SS</sub> or V <sub>CC</sub> |                     | 5                   | μA   |
| V <sub>IL</sub>                 | Input low voltage                |                                                                                                                | -0.45               | 0.3 V <sub>CC</sub> | V    |
| V <sub>IH</sub>                 | Input high voltage               |                                                                                                                | 0.7 V <sub>CC</sub> | V <sub>CC</sub> +1  | V    |
| V <sub>OL</sub> <sup>(1)</sup>  | Output low voltage               | I <sub>OL</sub> = 2 mA, V <sub>CC</sub> = 5 V                                                                  |                     | 0.4                 | V    |
| V <sub>OH</sub> <sup>(1)</sup>  | Output high voltage              | I <sub>OH</sub> = -2 mA, V <sub>CC</sub> = 5 V                                                                 | 0.8 V <sub>CC</sub> |                     | V    |
| V <sub>RES</sub> <sup>(2)</sup> | Internal reset threshold voltage |                                                                                                                | 1.0                 | 1.65                | V    |

1. For all 5 V range devices, the device meets the output requirements for both TTL and CMOS standards.

2. Characterized only, not 100% tested.

**Table 16. DC characteristics (M95160 and M95080, device grade 6)**

| Symbol          | Parameter                        | Test conditions                                                                         | Min.         | Max.         | Unit    |
|-----------------|----------------------------------|-----------------------------------------------------------------------------------------|--------------|--------------|---------|
| $I_{LI}$        | Input leakage current            | $V_{IN} = V_{SS} \text{ or } V_{CC}$                                                    |              | $\pm 2$      | $\mu A$ |
| $I_{LO}$        | Output leakage current           | $\overline{S} = V_{CC}, V_{OUT} = V_{SS} \text{ or } V_{CC}$                            |              | $\pm 2$      | $\mu A$ |
| $I_{CC}$        | Supply current                   | $C = 0.1V_{CC}/0.9V_{CC}$ at 10 MHz,<br>$V_{CC} = 5 \text{ V}$ , Q = open               |              | 5            | mA      |
| $I_{CC1}$       | Supply current (Standby)         | $\overline{S} = V_{CC}, V_{CC} = 5 \text{ V}$ ,<br>$V_{IN} = V_{SS} \text{ or } V_{CC}$ |              | 2            | $\mu A$ |
| $V_{IL}$        | Input low voltage                |                                                                                         | -0.45        | $0.3 V_{CC}$ | V       |
| $V_{IH}$        | Input high voltage               |                                                                                         | $0.7 V_{CC}$ | $V_{CC}+1$   | V       |
| $V_{OL}^{(1)}$  | Output low voltage               | $I_{OL} = 2 \text{ mA}$ , $V_{CC} = 5 \text{ V}$                                        |              | 0.4          | V       |
| $V_{OH}^{(1)}$  | Output high voltage              | $I_{OH} = -2 \text{ mA}$ , $V_{CC} = 5 \text{ V}$                                       | $0.8 V_{CC}$ |              | V       |
| $V_{RES}^{(2)}$ | Internal reset threshold voltage |                                                                                         | 1.0          | 1.65         | V       |

1. For all 5 V range devices, the device meets the output requirements for both TTL and CMOS standards.

2. Characterized only, not 100% tested.

**Table 17. DC characteristics (M95160-W and M95080-W, device grade 3)**

| Symbol          | Parameter                        | Test conditions                                                                        | Min.         | Max.         | Unit    |
|-----------------|----------------------------------|----------------------------------------------------------------------------------------|--------------|--------------|---------|
| $I_{LI}$        | Input leakage current            | $V_{IN} = V_{SS} \text{ or } V_{CC}$                                                   |              | $\pm 2$      | $\mu A$ |
| $I_{LO}$        | Output leakage current           | $\overline{S} = V_{CC}, V_{OUT} = V_{SS} \text{ or } V_{CC}$                           |              | $\pm 2$      | $\mu A$ |
| $I_{CC}$        | Supply current                   | $C = 0.1V_{CC}/0.9V_{CC}$ at 5 MHz,<br>$V_{CC} = 2.5 \text{ V}$ , Q = open             |              | 2            | mA      |
| $I_{CC1}$       | Supply current (Standby)         | $\overline{S} = V_{CC}, V_{CC} = 2.5 \text{ V}$ , $V_{IN} = V_{SS} \text{ or } V_{CC}$ |              | 2            | $\mu A$ |
| $V_{IL}$        | Input low voltage                |                                                                                        | -0.45        | $0.3 V_{CC}$ | V       |
| $V_{IH}$        | Input high voltage               |                                                                                        | $0.7 V_{CC}$ | $V_{CC}+1$   | V       |
| $V_{OL}$        | Output low voltage               | $I_{OL} = 1.5 \text{ mA}$ , $V_{CC} = 2.5 \text{ V}$                                   |              | 0.4          | V       |
| $V_{OH}$        | Output high voltage              | $I_{OH} = -0.4 \text{ mA}$ , $V_{CC} = 2.5 \text{ V}$                                  | $0.8 V_{CC}$ |              | V       |
| $V_{RES}^{(1)}$ | Internal reset threshold voltage |                                                                                        | 1.0          | 1.65         | V       |

1. Characterized only, not 100% tested.

**Table 18. DC characteristics (M95160-W and M95080-W, device grade 6)**

| Symbol          | Parameter                        | Test conditions                                                                       | Min.         | Max.         | Unit    |
|-----------------|----------------------------------|---------------------------------------------------------------------------------------|--------------|--------------|---------|
| $I_{LI}$        | Input leakage current            | $V_{IN} = V_{SS} \text{ or } V_{CC}$                                                  |              | $\pm 2$      | $\mu A$ |
| $I_{LO}$        | Output leakage current           | $\overline{S} = V_{CC}, V_{OUT} = V_{SS} \text{ or } V_{CC}$                          |              | $\pm 2$      | $\mu A$ |
| $I_{CC}$        | Supply current                   | $C = 0.1V_{CC}/0.9V_{CC}$ at 5 MHz,<br>$V_{CC} = 2.5V$ , Q = open, Process SA         |              | 2            | mA      |
|                 |                                  | $C = 0.1V_{CC}/0.9V_{CC}$ at 10 MHz,<br>$V_{CC} = 2.5V$ , Q = open, Process GB or SB  |              | 5            | mA      |
| $I_{CC1}$       | Supply current (Standby)         | $\overline{S} = V_{CC}, 2.5V < V_{CC} < 5.5V$<br>$V_{IN} = V_{SS} \text{ or } V_{CC}$ |              | 2            | $\mu A$ |
| $V_{IL}$        | Input low voltage                |                                                                                       | -0.45        | $0.3 V_{CC}$ | V       |
| $V_{IH}$        | Input high voltage               |                                                                                       | $0.7 V_{CC}$ | $V_{CC}+1$   | V       |
| $V_{OL}$        | Output low voltage               | $I_{OL} = 1.5 \text{ mA}, V_{CC} = 2.5V$                                              |              | 0.4          | V       |
| $V_{OH}$        | Output high voltage              | $I_{OH} = -0.4 \text{ mA}, V_{CC} = 2.5V$                                             | $0.8 V_{CC}$ |              | V       |
| $V_{RES}^{(1)}$ | Internal reset threshold voltage |                                                                                       | 1.0          | 1.65         | V       |

1. Characterized only, not 100% tested.

**Table 19. DC characteristics (M95160-R and M95080-R)<sup>(1)</sup>**

| Symbol          | Parameter                        | Test conditions                                                                                                           | Min.         | Max.         | Unit    |
|-----------------|----------------------------------|---------------------------------------------------------------------------------------------------------------------------|--------------|--------------|---------|
| $I_{LI}$        | Input leakage current            | $V_{IN} = V_{SS}$ or $V_{CC}$                                                                                             |              | $\pm 2$      | $\mu A$ |
| $I_{LO}$        | Output leakage current           | $S = V_{CC}$ , voltage applied on $Q = V_{SS}$ or $V_{CC}$                                                                |              | $\pm 2$      | $\mu A$ |
| $I_{CCR}$       | Supply current (Read)            | $V_{CC} = 2.5 V$ , $C = 0.1 V_{CC}$ or $0.9V_{CC}$ , $f_C = 5 MHz$ , $Q = open$                                           |              | 3            | mA      |
|                 |                                  | $V_{CC} = 1.8 V$ , $C = 0.1V_{CC}$ or $0.9V_{CC}$ at max clock frequency, $Q = open$                                      |              | 2            | mA      |
| $I_{CC1}$       | Supply current (Standby)         | $V_{CC} = 5.0 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$                                                |              | 2            | $\mu A$ |
|                 |                                  | $V_{CC} = 2.5 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$                                                |              | 1            | $\mu A$ |
|                 |                                  | $V_{CC} = 1.8 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$                                                |              | 1            | $\mu A$ |
| $V_{IL}$        | Input low voltage                | $2.5V < V_{CC} < 5.5V$                                                                                                    | -0.45        | $0.3V_{CC}$  | V       |
|                 |                                  | $1.8V < V_{CC} < 2.5V$                                                                                                    | -0.45        | $0.25V_{CC}$ | V       |
| $V_{IH}$        | Input high voltage               | $2.5V < V_{CC} < 5.5V$                                                                                                    | $0.7V_{CC}$  | $V_{CC}+1$   | V       |
|                 |                                  | $1.8V < V_{CC} < 2.5V$                                                                                                    | $0.75V_{CC}$ | $V_{CC}+1$   | V       |
| $V_{OL}$        | Output low voltage               | $V_{CC} = 2.5 V$ , $I_{OL} = 1.5 mA$ , or $V_{CC} = 5.5 V$ , $I_{OL} = 2 mA$                                              |              | $0.2V_{CC}$  | V       |
|                 |                                  | $V_{CC} = 1.8 V$ , $I_{OL} = 0.15 mA$                                                                                     |              | 0.3          | V       |
| $V_{OH}$        | Output high voltage              | $V_{CC} = 2.5 V$ , $I_{OH} = -0.4 mA$ , or $V_{CC} = 5.5 V$ , $I_{OH} = -2 mA$ , or $V_{CC} = 1.8 V$ , $I_{OH} = -0.1 mA$ | $0.8V_{CC}$  |              | V       |
| $V_{RES}^{(2)}$ | Internal reset threshold voltage |                                                                                                                           | 1.0          | 1.65         | V       |

1. If the application uses the M95080-R and M95160-R at  $2.5 V \leq V_{CC} \leq 5.5 V$  and  $-40^\circ C \leq T_A \leq +85^\circ C$ , please refer to [Table 16: DC characteristics \(M95160 and M95080, device grade 6\)](#) instead of the above table.

2. Characterized only, not 100% tested.

Table 20. DC characteristics (M95160-F)

| Symbol          | Parameter                        | Test conditions                                                                                                           | Min.         | Max.         | Unit    |
|-----------------|----------------------------------|---------------------------------------------------------------------------------------------------------------------------|--------------|--------------|---------|
| $I_{LI}$        | Input leakage current            | $V_{IN} = V_{SS}$ or $V_{CC}$                                                                                             |              | $\pm 2$      | $\mu A$ |
| $I_{LO}$        | Output leakage current           | $S = V_{CC}$ , voltage applied on $Q = V_{SS}$ or $V_{CC}$                                                                |              | $\pm 2$      | $\mu A$ |
| $I_{CCR}$       | Supply current (Read)            | $V_{CC} = 2.5 V$ , $C = 0.1 V_{CC}$ or $0.9V_{CC}$ , $f_C = 5 MHz$ , $Q = open$                                           |              | 3            | mA      |
|                 |                                  | $V_{CC} = 1.7 V$ , $C = 0.1V_{CC}$ or $0.9V_{CC}$ at max clock frequency, $Q = open$                                      |              | 2            | mA      |
| $I_{CC1}$       | Supply current (Standby)         | $V_{CC} = 5.0 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$                                                |              | 2            | $\mu A$ |
|                 |                                  | $V_{CC} = 2.5 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$                                                |              | 1            | $\mu A$ |
|                 |                                  | $V_{CC} = 1.7 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$                                                |              | 1            | $\mu A$ |
| $V_{IL}$        | Input low voltage                | $2.5 V < V_{CC} < 5.5 V$                                                                                                  | -0.45        | $0.3V_{CC}$  | V       |
|                 |                                  | $1.8 < V_{CC} < 2.5 V$                                                                                                    | -0.45        | $0.25V_{CC}$ | V       |
|                 |                                  | $1.7 V < V_{CC} < 1.8 V$                                                                                                  | -0.45        | $0.20V_{CC}$ | V       |
| $V_{IH}$        | Input high voltage               | $2.5 V < V_{CC} < 5.5 V$                                                                                                  | $0.7V_{CC}$  | $V_{CC}+1$   | V       |
|                 |                                  | $1.7 V < V_{CC} < 2.5 V$                                                                                                  | $0.75V_{CC}$ | $V_{CC}+1$   | V       |
| $V_{OL}$        | Output low voltage               | $V_{CC} = 2.5 V$ , $I_{OL} = 1.5 mA$ , or $V_{CC} = 5.5 V$ , $I_{OL} = 2 mA$                                              |              | $0.2V_{CC}$  | V       |
|                 |                                  | $V_{CC} = 1.7 V$ , $I_{OL} = 0.15 mA$                                                                                     |              | 0.2          | V       |
| $V_{OH}$        | Output high voltage              | $V_{CC} = 2.5 V$ , $I_{OH} = -0.4 mA$ , or $V_{CC} = 5.5 V$ , $I_{OH} = -2 mA$ , or $V_{CC} = 1.7 V$ , $I_{OH} = -0.1 mA$ | $0.8V_{CC}$  |              | V       |
| $V_{RES}^{(1)}$ | Internal reset threshold voltage |                                                                                                                           | 1.0          | 1.65         | V       |

1. Characterized only, not 100% tested.

**Table 21. AC characteristics (M95160 and M95080, device grade 3)**

| Test conditions specified in <a href="#">Table 13</a> and <a href="#">Table 9</a> . |            |                                                           |      |      |         |
|-------------------------------------------------------------------------------------|------------|-----------------------------------------------------------|------|------|---------|
| Symbol                                                                              | Alt.       | Parameter                                                 | Min. | Max. | Unit    |
| $f_C$                                                                               | $f_{SCK}$  | Clock frequency                                           | D.C. | 5    | MHz     |
| $t_{SLCH}$                                                                          | $t_{CSS1}$ | $\overline{S}$ active setup time                          | 90   |      | ns      |
| $t_{SHCH}$                                                                          | $t_{CSS2}$ | $\overline{S}$ not active setup time                      | 90   |      | ns      |
| $t_{SHSL}$                                                                          | $t_{CS}$   | $\overline{S}$ deselect time                              | 100  |      | ns      |
| $t_{CHSH}$                                                                          | $t_{CSH}$  | $\overline{S}$ active hold time                           | 90   |      | ns      |
| $t_{CHSL}$                                                                          |            | $\overline{S}$ not active hold time                       | 90   |      | ns      |
| $t_{CH}^{(1)}$                                                                      | $t_{CLH}$  | Clock high time                                           | 90   |      | ns      |
| $t_{CL}^{(1)}$                                                                      | $t_{CLL}$  | Clock low time                                            | 90   |      | ns      |
| $t_{CLCH}^{(2)}$                                                                    | $t_{RC}$   | Clock rise time                                           |      | 1    | $\mu s$ |
| $t_{CHCL}^{(2)}$                                                                    | $t_{FC}$   | Clock fall time                                           |      | 1    | $\mu s$ |
| $t_{DVCH}$                                                                          | $t_{DSU}$  | Data in setup time                                        | 20   |      | ns      |
| $t_{CHDX}$                                                                          | $t_{DH}$   | Data in hold time                                         | 30   |      | ns      |
| $t_{HHCH}$                                                                          |            | Clock low hold time after $\overline{HOLD}$ not active    | 70   |      | ns      |
| $t_{HLCH}$                                                                          |            | Clock low hold time after $\overline{HOLD}$ active        | 40   |      | ns      |
| $t_{CLHL}$                                                                          |            | Clock low set-up time before $\overline{HOLD}$ active     | 0    |      | ns      |
| $t_{CLHH}$                                                                          |            | Clock low set-up time before $\overline{HOLD}$ not active | 0    |      | ns      |
| $t_{SHQZ}^{(2)}$                                                                    | $t_{DIS}$  | Output disable time                                       |      | 100  | ns      |
| $t_{CLQV}$                                                                          | $t_V$      | Clock low to output valid                                 |      | 60   | ns      |
| $t_{CLQX}$                                                                          | $t_{HO}$   | Output hold time                                          | 0    |      | ns      |
| $t_{QLQH}^{(2)}$                                                                    | $t_{RO}$   | Output rise time                                          |      | 50   | ns      |
| $t_{QHQL}^{(2)}$                                                                    | $t_{FO}$   | Output fall time                                          |      | 50   | ns      |
| $t_{HHQV}$                                                                          | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                    |      | 50   | ns      |
| $t_{HLQZ}^{(2)}$                                                                    | $t_{HZ}$   | $\overline{HOLD}$ low to output high-Z                    |      | 100  | ns      |
| $t_W$                                                                               | $t_{WC}$   | Write time                                                |      | 5    | ms      |

1.  $t_{CH} + t_{CL}$  must never be lower than the shortest possible clock period,  $1/f_C(\max)$ .

2. Value guaranteed by characterization, not 100% tested in production.

**Table 22. AC characteristics (M95160 and M95080, device grade 6)**

| Test conditions specified in <a href="#">Table 13.</a> and <a href="#">Table 9.</a> |            |                                                           |      |      |         |
|-------------------------------------------------------------------------------------|------------|-----------------------------------------------------------|------|------|---------|
| Symbol                                                                              | Alt.       | Parameter                                                 | Min. | Max. | Unit    |
| $f_C$                                                                               | $f_{SCK}$  | Clock frequency                                           | D.C. | 10   | MHz     |
| $t_{SLCH}$                                                                          | $t_{CSS1}$ | $\overline{S}$ active setup time                          | 15   |      | ns      |
| $t_{SHCH}$                                                                          | $t_{CSS2}$ | $\overline{S}$ not active setup time                      | 15   |      | ns      |
| $t_{SHSL}$                                                                          | $t_{CS}$   | $\overline{S}$ deselect time                              | 40   |      | ns      |
| $t_{CHSH}$                                                                          | $t_{CSH}$  | $\overline{S}$ active hold time                           | 25   |      | ns      |
| $t_{CHSL}$                                                                          |            | $\overline{S}$ not active hold time                       | 15   |      | ns      |
| $t_{CH}^{(1)}$                                                                      | $t_{CLH}$  | Clock high time                                           | 40   |      | ns      |
| $t_{CL}^{(1)}$                                                                      | $t_{CLL}$  | Clock low time                                            | 40   |      | ns      |
| $t_{CLCH}^{(2)}$                                                                    | $t_{RC}$   | Clock rise time                                           |      | 1    | $\mu s$ |
| $t_{CHCL}^{(2)}$                                                                    | $t_{FC}$   | Clock fall time                                           |      | 1    | $\mu s$ |
| $t_{DVCH}$                                                                          | $t_{DSU}$  | Data in setup time                                        | 15   |      | ns      |
| $t_{CHDX}$                                                                          | $t_{DH}$   | Data in hold time                                         | 15   |      | ns      |
| $t_{HHCH}$                                                                          |            | Clock low hold time after $\overline{HOLD}$ not active    | 15   |      | ns      |
| $t_{HLCH}$                                                                          |            | Clock low hold time after $\overline{HOLD}$ active        | 20   |      | ns      |
| $t_{CLHL}$                                                                          |            | Clock low set-up time before $\overline{HOLD}$ active     | 0    |      | ns      |
| $t_{CLHH}$                                                                          |            | Clock low set-up time before $\overline{HOLD}$ not active | 0    |      | ns      |
| $t_{SHQZ}^{(2)}$                                                                    | $t_{DIS}$  | Output disable time                                       |      | 25   | ns      |
| $t_{CLQV}$                                                                          | $t_V$      | Clock low to output valid                                 |      | 35   | ns      |
| $t_{CLQX}$                                                                          | $t_{HO}$   | Output hold time                                          | 0    |      | ns      |
| $t_{QLQH}^{(2)}$                                                                    | $t_{RO}$   | Output rise time                                          |      | 20   | ns      |
| $t_{QHQL}^{(2)}$                                                                    | $t_{FO}$   | Output fall time                                          |      | 20   | ns      |
| $t_{HHQV}$                                                                          | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                    |      | 25   | ns      |
| $t_{HLQZ}^{(2)}$                                                                    | $t_{HZ}$   | $\overline{HOLD}$ low to output high-Z                    |      | 35   | ns      |
| $t_W$                                                                               | $t_{WC}$   | Write Time                                                |      | 5    | ms      |

1.  $t_{CH} + t_{CL}$  must never be lower than the shortest possible clock period,  $1/f_C(\max)$ .

2. Value guaranteed by characterization, not 100% tested in production.

**Table 23. AC characteristics (M95160-W and M95080-W, device grade 3)**

| Test conditions specified in <a href="#">Table 13.</a> and <a href="#">Table 10.</a> |            |                                                           |      |      |         |
|--------------------------------------------------------------------------------------|------------|-----------------------------------------------------------|------|------|---------|
| Symbol                                                                               | Alt.       | Parameter                                                 | Min. | Max. | Unit    |
| $f_C$                                                                                | $f_{SCK}$  | Clock frequency                                           | D.C. | 5    | MHz     |
| $t_{SLCH}$                                                                           | $t_{CSS1}$ | $\overline{S}$ active setup time                          | 90   |      | ns      |
| $t_{SHCH}$                                                                           | $t_{CSS2}$ | $\overline{S}$ not active setup time                      | 90   |      | ns      |
| $t_{SHSL}$                                                                           | $t_{CS}$   | $\overline{S}$ deselect time                              | 100  |      | ns      |
| $t_{CHSH}$                                                                           | $t_{CSH}$  | $\overline{S}$ active hold time                           | 90   |      | ns      |
| $t_{CHSL}$                                                                           |            | $\overline{S}$ not active hold time                       | 90   |      | ns      |
| $t_{CH}^{(1)}$                                                                       | $t_{CLH}$  | Clock high time                                           | 90   |      | ns      |
| $t_{CL}^{(1)}$                                                                       | $t_{CLL}$  | Clock low time                                            | 90   |      | ns      |
| $t_{CLCH}^{(2)}$                                                                     | $t_{RC}$   | Clock rise time                                           |      | 1    | $\mu s$ |
| $t_{CHCL}^{(2)}$                                                                     | $t_{FC}$   | Clock fall time                                           |      | 1    | $\mu s$ |
| $t_{DVCH}$                                                                           | $t_{DSU}$  | Data in setup time                                        | 20   |      | ns      |
| $t_{CHDX}$                                                                           | $t_{DH}$   | Data in hold time                                         | 30   |      | ns      |
| $t_{HHCH}$                                                                           |            | Clock low hold time after $\overline{HOLD}$ not active    | 70   |      | ns      |
| $t_{HLCH}$                                                                           |            | Clock low hold time after $\overline{HOLD}$ active        | 40   |      | ns      |
| $t_{CLHL}$                                                                           |            | Clock low set-up time before $\overline{HOLD}$ active     | 0    |      | ns      |
| $t_{CLHH}$                                                                           |            | Clock low set-up time before $\overline{HOLD}$ not active | 0    |      | ns      |
| $t_{SHQZ}^{(2)}$                                                                     | $t_{DIS}$  | Output disable time                                       |      | 100  | ns      |
| $t_{CLQV}$                                                                           | $t_V$      | Clock low to output valid                                 |      | 60   | ns      |
| $t_{CLQX}$                                                                           | $t_{HO}$   | Output hold time                                          | 0    |      | ns      |
| $t_{QLQH}^{(2)}$                                                                     | $t_{RO}$   | Output rise time                                          |      | 50   | ns      |
| $t_{QHQL}^{(2)}$                                                                     | $t_{FO}$   | Output fall time                                          |      | 50   | ns      |
| $t_{HHQV}$                                                                           | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                    |      | 50   | ns      |
| $t_{HLQZ}^{(2)}$                                                                     | $t_{HZ}$   | $\overline{HOLD}$ low to output high-Z                    |      | 100  | ns      |
| $t_W$                                                                                | $t_{WC}$   | Write time                                                |      | 5    | ms      |

1.  $t_{CH} + t_{CL}$  must never be lower than the shortest possible clock period,  $1/f_C(\max)$ .

2. Value guaranteed by characterization, not 100% tested in production.

**Table 24. AC characteristics (M95160-W and M95080-W, device grade 6)**

| Test conditions specified in <a href="#">Table 13.</a> and <a href="#">Table 10.</a> |            |                                                           |      |                   |         |
|--------------------------------------------------------------------------------------|------------|-----------------------------------------------------------|------|-------------------|---------|
| Symbol                                                                               | Alt.       | Parameter                                                 | Min. | Max.              | Unit    |
| $f_C$                                                                                | $f_{SCK}$  | Clock frequency                                           | D.C. | 10                | MHz     |
| $t_{SLCH}$                                                                           | $t_{CSS1}$ | $\overline{S}$ active setup time                          | 30   |                   | ns      |
| $t_{SHCH}$                                                                           | $t_{CSS2}$ | $\overline{S}$ not active setup time                      | 30   |                   | ns      |
| $t_{SHSL}$                                                                           | $t_{CS}$   | $\overline{S}$ deselect time                              | 40   |                   | ns      |
| $t_{CHSH}$                                                                           | $t_{CSH}$  | $\overline{S}$ active hold time                           | 30   |                   | ns      |
| $t_{CHSL}$                                                                           |            | $\overline{S}$ not active hold time                       | 30   |                   | ns      |
| $t_{CH}^{(1)}$                                                                       | $t_{CLH}$  | Clock high time                                           | 40   |                   | ns      |
| $t_{CL}^{(1)}$                                                                       | $t_{CLL}$  | Clock low time                                            | 40   |                   | ns      |
| $t_{CLCH}^{(2)}$                                                                     | $t_{RC}$   | Clock rise time                                           |      | 2                 | $\mu$ s |
| $t_{CHCL}^{(2)}$                                                                     | $t_{FC}$   | Clock fall time                                           |      | 2                 | $\mu$ s |
| $t_{DVCH}$                                                                           | $t_{DSU}$  | Data in setup time                                        | 10   |                   | ns      |
| $t_{CHDX}$                                                                           | $t_{DH}$   | Data in hold time                                         | 10   |                   | ns      |
| $t_{HHCH}$                                                                           |            | Clock low hold time after $\overline{HOLD}$ not active    | 30   |                   | ns      |
| $t_{HLCH}$                                                                           |            | Clock low hold time after $\overline{HOLD}$ active        | 30   |                   | ns      |
| $t_{CLHL}$                                                                           |            | Clock low set-up time before $\overline{HOLD}$ active     | 0    |                   | ns      |
| $t_{CLHH}$                                                                           |            | Clock low set-up time before $\overline{HOLD}$ not active | 0    |                   | ns      |
| $t_{SHQZ}^{(2)}$                                                                     | $t_{DIS}$  | Output disable time                                       |      | 40                | ns      |
| $t_{CLQV}$                                                                           | $t_V$      | Clock low to output valid                                 |      | 40 <sup>(3)</sup> | ns      |
| $t_{CLQX}$                                                                           | $t_{HO}$   | Output hold time                                          | 0    |                   | ns      |
| $t_{QLQH}^{(2)}$                                                                     | $t_{RO}$   | Output rise time                                          |      | 40                | ns      |
| $t_{QHQL}^{(2)}$                                                                     | $t_{FO}$   | Output fall time                                          |      | 40                | ns      |
| $t_{HHQV}$                                                                           | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                    |      | 40                | ns      |
| $t_{HLQZ}^{(2)}$                                                                     | $t_{HZ}$   | $\overline{HOLD}$ low to output high-Z                    |      | 40                | ns      |
| $t_W$                                                                                | $t_{WC}$   | Write time                                                |      | 5                 | ms      |

- $t_{CH} + t_{CL}$  must never be lower than the shortest possible clock period,  $1/f_C(\text{max})$ .
- Value guaranteed by characterization, not 100% tested in production.
- $t_{CLQV}$  must be compatible with  $t_{CL}$  (clock low time): if the SPI bus master offers a Read setup time  $t_{SU} = 0$  ns,  $t_{CL}$  can be equal to (or greater than)  $t_{CLQV}$ . In all other cases,  $t_{CL}$  must be equal to (or greater than)  $t_{CLQV} + t_{SU}$ .

**Table 25. AC characteristics for M95160-Wxx6/S and M95080-Wxx6/S**

| Test conditions specified in <a href="#">Table 10</a> and <a href="#">Table 13</a> |            |                                                           |      |      |         |
|------------------------------------------------------------------------------------|------------|-----------------------------------------------------------|------|------|---------|
| Symbol                                                                             | Alt.       | Parameter                                                 | Min. | Max. | Unit    |
| $f_C$                                                                              | $f_{SCK}$  | Clock frequency                                           | D.C. | 5    | MHz     |
| $t_{SLCH}$                                                                         | $t_{CSS1}$ | $\overline{S}$ active setup time                          | 90   |      | ns      |
| $t_{SHCH}$                                                                         | $t_{CSS2}$ | $\overline{S}$ not active setup time                      | 90   |      | ns      |
| $t_{SHSL}$                                                                         | $t_{CS}$   | $\overline{S}$ deselect time                              | 100  |      | ns      |
| $t_{CHSH}$                                                                         | $t_{CSH}$  | $\overline{S}$ active hold time                           | 90   |      | ns      |
| $t_{CHSL}$                                                                         |            | $\overline{S}$ not active hold time                       | 90   |      | ns      |
| $t_{CH}^{(1)}$                                                                     | $t_{CLH}$  | Clock high time                                           | 90   |      | ns      |
| $t_{CL}^{(1)}$                                                                     | $t_{CLL}$  | Clock low time                                            | 90   |      | ns      |
| $t_{CLCH}^{(2)}$                                                                   | $t_{RC}$   | Clock rise time                                           |      | 1    | $\mu$ s |
| $t_{CHCL}^{(2)}$                                                                   | $t_{FC}$   | Clock fall time                                           |      | 1    | $\mu$ s |
| $t_{DVCH}$                                                                         | $t_{DSU}$  | Data in setup time                                        | 20   |      | ns      |
| $t_{CHDX}$                                                                         | $t_{DH}$   | Data in hold time                                         | 30   |      | ns      |
| $t_{HHCH}$                                                                         |            | Clock low hold time after $\overline{HOLD}$ not active    | 70   |      | ns      |
| $t_{HLCH}$                                                                         |            | Clock low hold time after $\overline{HOLD}$ active        | 40   |      | ns      |
| $t_{CLHL}$                                                                         |            | Clock low set-up time before $\overline{HOLD}$ active     | 0    |      | ns      |
| $t_{CLHH}$                                                                         |            | Clock low set-up time before $\overline{HOLD}$ not active | 0    |      | ns      |
| $t_{SHQZ}^{(2)}$                                                                   | $t_{DIS}$  | Output disable time                                       |      | 100  | ns      |
| $t_{CLQV}$                                                                         | $t_V$      | Clock low to output valid                                 |      | 60   | ns      |
| $t_{CLQX}$                                                                         | $t_{HO}$   | Output hold time                                          | 0    |      | ns      |
| $t_{QLQH}^{(2)}$                                                                   | $t_{RO}$   | Output rise time                                          |      | 50   | ns      |
| $t_{QHQL}^{(2)}$                                                                   | $t_{FO}$   | Output fall time                                          |      | 50   | ns      |
| $t_{HHQV}$                                                                         | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                    |      | 50   | ns      |
| $t_{HLQZ}^{(2)}$                                                                   | $t_{HZ}$   | $\overline{HOLD}$ low to output high-Z                    |      | 100  | ns      |
| $t_W$                                                                              | $t_{WC}$   | Write time                                                |      | 5    | ms      |

1.  $t_{CH} + t_{CL}$  must never be lower than the shortest possible clock period,  $1/f_C(\max)$ .

2. Value guaranteed by characterization, not 100% tested in production.

**Table 26. AC characteristics (M95160-R and M95080-R)**

| Test conditions specified in <a href="#">Table 13</a> and <a href="#">Table 11</a> |            |                                                           |      |      |         |
|------------------------------------------------------------------------------------|------------|-----------------------------------------------------------|------|------|---------|
| Symbol                                                                             | Alt.       | Parameter                                                 | Min. | Max. | Unit    |
| $f_C$                                                                              | $f_{SCK}$  | Clock frequency                                           | D.C. | 5    | MHz     |
| $t_{SLCH}$                                                                         | $t_{CSS1}$ | $\overline{S}$ active setup time                          | 60   |      | ns      |
| $t_{SHCH}$                                                                         | $t_{CSS2}$ | $\overline{S}$ not active setup time                      | 60   |      | ns      |
| $t_{SHSL}$                                                                         | $t_{CS}$   | $\overline{S}$ deselect time                              | 90   |      | ns      |
| $t_{CHSH}$                                                                         | $t_{CSH}$  | $\overline{S}$ active hold time                           | 60   |      | ns      |
| $t_{CHSL}$                                                                         |            | $\overline{S}$ not active hold time                       | 60   |      | ns      |
| $t_{CH}^{(1)}$                                                                     | $t_{CLH}$  | Clock high time                                           | 80   |      | ns      |
| $t_{CL}^{(1)}$                                                                     | $t_{CLL}$  | Clock low time                                            | 80   |      | ns      |
| $t_{CLCH}^{(2)}$                                                                   | $t_{RC}$   | Clock rise time                                           |      | 2    | $\mu s$ |
| $t_{CHCL}^{(2)}$                                                                   | $t_{FC}$   | Clock fall time                                           |      | 2    | $\mu s$ |
| $t_{DVCH}$                                                                         | $t_{DSU}$  | Data in setup time                                        | 20   |      | ns      |
| $t_{CHDX}$                                                                         | $t_{DH}$   | Data in hold time                                         | 20   |      | ns      |
| $t_{HHCH}$                                                                         |            | Clock low hold time after $\overline{HOLD}$ not active    | 60   |      | ns      |
| $t_{HLCH}$                                                                         |            | Clock low hold time after $\overline{HOLD}$ active        | 60   |      | ns      |
| $t_{CLHL}$                                                                         |            | Clock low set-up time before $\overline{HOLD}$ active     | 0    |      | 0       |
| $t_{CLHH}$                                                                         |            | Clock low set-up time before $\overline{HOLD}$ not active | 0    |      | 0       |
| $t_{SHQZ}^{(2)}$                                                                   | $t_{DIS}$  | Output disable time                                       |      | 80   | ns      |
| $t_{CLQV}$                                                                         | $t_V$      | Clock low to output valid                                 |      | 80   | ns      |
| $t_{CLQX}$                                                                         | $t_{HO}$   | Output hold time                                          | 0    |      | ns      |
| $t_{QLQH}^{(2)}$                                                                   | $t_{RO}$   | Output rise time                                          |      | 80   | ns      |
| $t_{QHQL}^{(2)}$                                                                   | $t_{FO}$   | Output fall time                                          |      | 80   | ns      |
| $t_{HHQV}$                                                                         | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                    |      | 80   | ns      |
| $t_{HLQZ}^{(2)}$                                                                   | $t_{HZ}$   | $\overline{HOLD}$ low to output high-Z                    |      | 80   | ns      |
| $t_W$                                                                              | $t_{WC}$   | Write time                                                |      | 5    | ms      |

1.  $t_{CH} + t_{CL}$  must never be lower than the shortest possible clock period,  $1/f_C(\max)$ .

2. Value guaranteed by characterization, not 100% tested in production.

Table 27. AC characteristics (M95160-F)<sup>(1)</sup>

| Test conditions specified in <a href="#">Table 12</a> |            |                                                           |      |      |         |
|-------------------------------------------------------|------------|-----------------------------------------------------------|------|------|---------|
| Symbol                                                | Alt.       | Parameter                                                 | Min. | Max. | Unit    |
| $f_C$                                                 | $f_{SCK}$  | Clock frequency                                           | D.C. | 3.5  | MHz     |
| $t_{SLCH}$                                            | $t_{CSS1}$ | $\overline{S}$ active setup time                          | 85   |      | ns      |
| $t_{SHCH}$                                            | $t_{CSS2}$ | $\overline{S}$ not active setup time                      | 85   |      | ns      |
| $t_{SHSL}$                                            | $t_{CS}$   | $\overline{S}$ deselect time                              | 120  |      | ns      |
| $t_{CHSH}$                                            | $t_{CSH}$  | $\overline{S}$ active hold time                           | 85   |      | ns      |
| $t_{CHSL}$                                            |            | $\overline{S}$ not active hold time                       | 85   |      | ns      |
| $t_{CH}^{(2)}$                                        | $t_{CLH}$  | Clock high time                                           | 110  |      | ns      |
| $t_{CL}^{(1)}$                                        | $t_{CLL}$  | Clock low time                                            | 110  |      | ns      |
| $t_{CLCH}^{(3)}$                                      | $t_{RC}$   | Clock rise time                                           |      | 2    | $\mu s$ |
| $t_{CHCL}^{(2)}$                                      | $t_{FC}$   | Clock fall time                                           |      | 2    | $\mu s$ |
| $t_{DVCH}$                                            | $t_{DSU}$  | Data in setup time                                        | 30   |      | ns      |
| $t_{CHDX}$                                            | $t_{DH}$   | Data in hold time                                         | 30   |      | ns      |
| $t_{HHCH}$                                            |            | Clock low hold time after $\overline{HOLD}$ not active    | 85   |      | ns      |
| $t_{HLCH}$                                            |            | Clock low hold time after $\overline{HOLD}$ active        | 85   |      | ns      |
| $t_{CLHL}$                                            |            | Clock low set-up time before $\overline{HOLD}$ active     | 0    |      | 0       |
| $t_{CLHH}$                                            |            | Clock low set-up time before $\overline{HOLD}$ not active | 0    |      | 0       |
| $t_{SHQZ}^{(2)}$                                      | $t_{DIS}$  | Output disable time                                       |      | 120  | ns      |
| $t_{CLQV}$                                            | $t_V$      | Clock low to output valid                                 |      | 120  | ns      |
| $t_{CLQX}$                                            | $t_{HO}$   | Output hold time                                          | 0    |      | ns      |
| $t_{QLQH}^{(2)}$                                      | $t_{RO}$   | Output rise time                                          |      | 100  | ns      |
| $t_{QHQL}^{(2)}$                                      | $t_{FO}$   | Output fall time                                          |      | 100  | ns      |
| $t_{HHQV}$                                            | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                    |      | 110  | ns      |
| $t_{HLQZ}^{(2)}$                                      | $t_{HZ}$   | $\overline{HOLD}$ low to output high-Z                    |      | 110  | ns      |
| $t_W$                                                 | $t_{WC}$   | Write time                                                |      | 5    | ms      |

1. Preliminary data.

2.  $t_{CH} + t_{CL}$  must never be lower than the shortest possible clock period,  $1/f_C(\max)$ .

3. Value guaranteed by characterization, not 100% tested in production.

Figure 15. Serial input timing

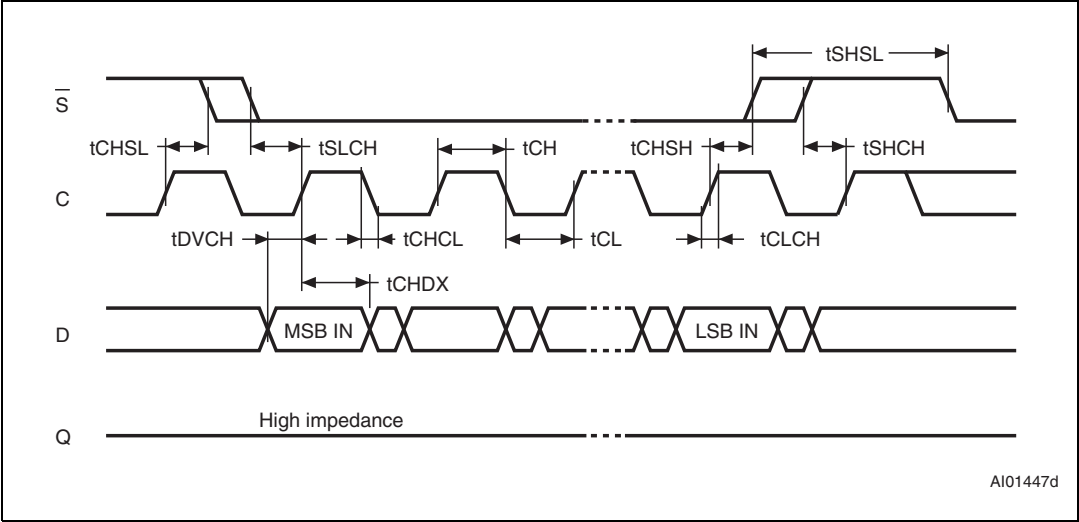


Figure 16. Hold timing

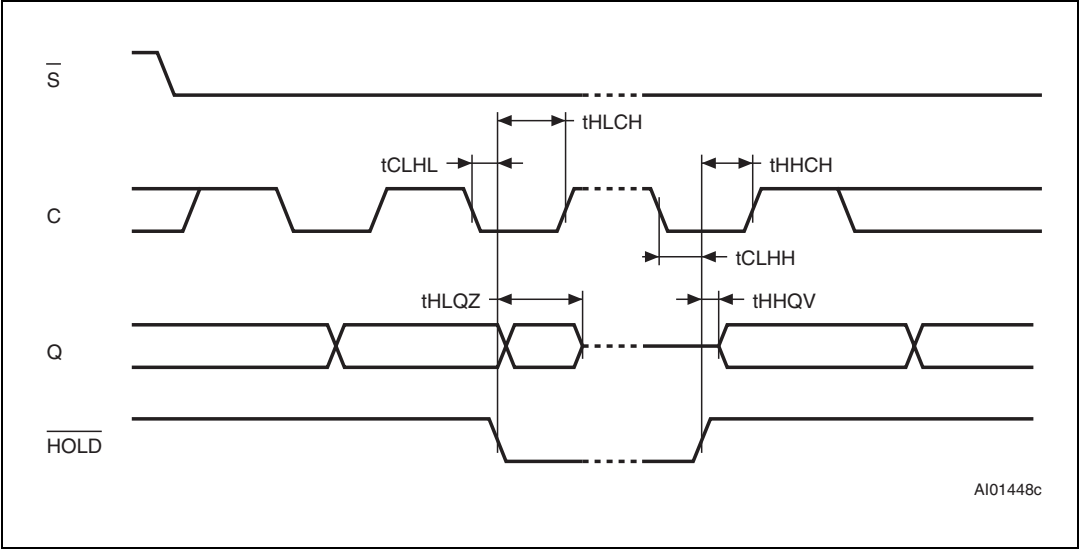
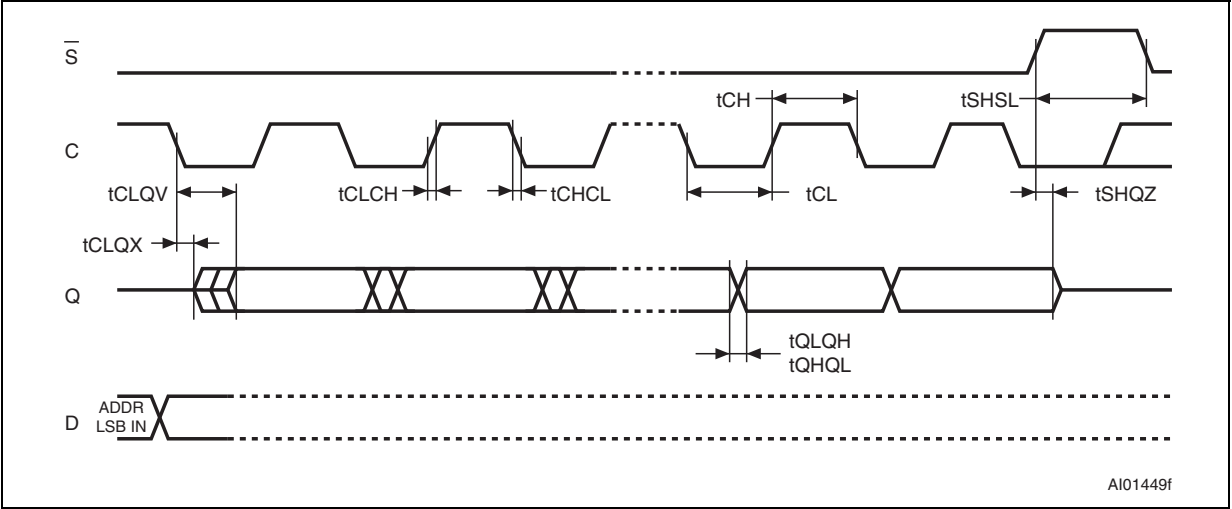


Figure 17. Serial output timing

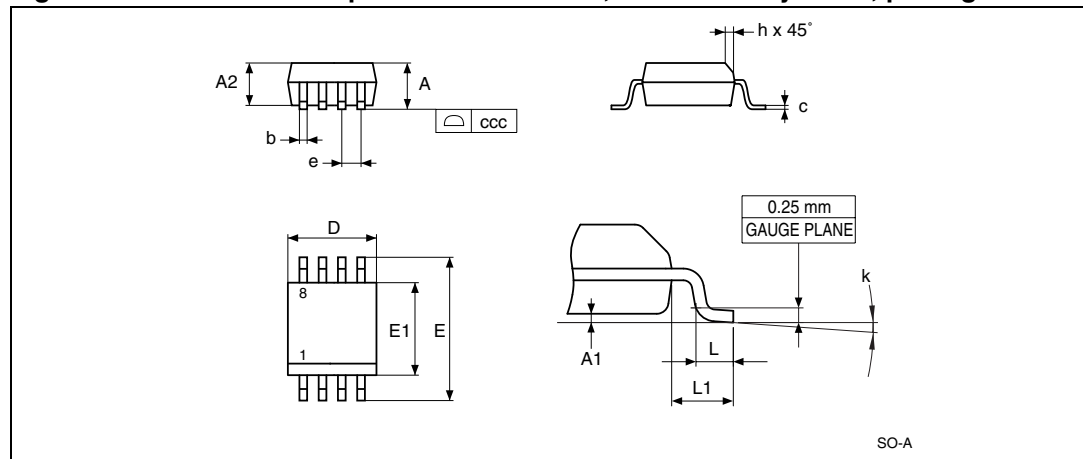


AI01449f

## 10 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

**Figure 18. SO8N – 8-lead plastic small outline, 150 mils body width, package outline**



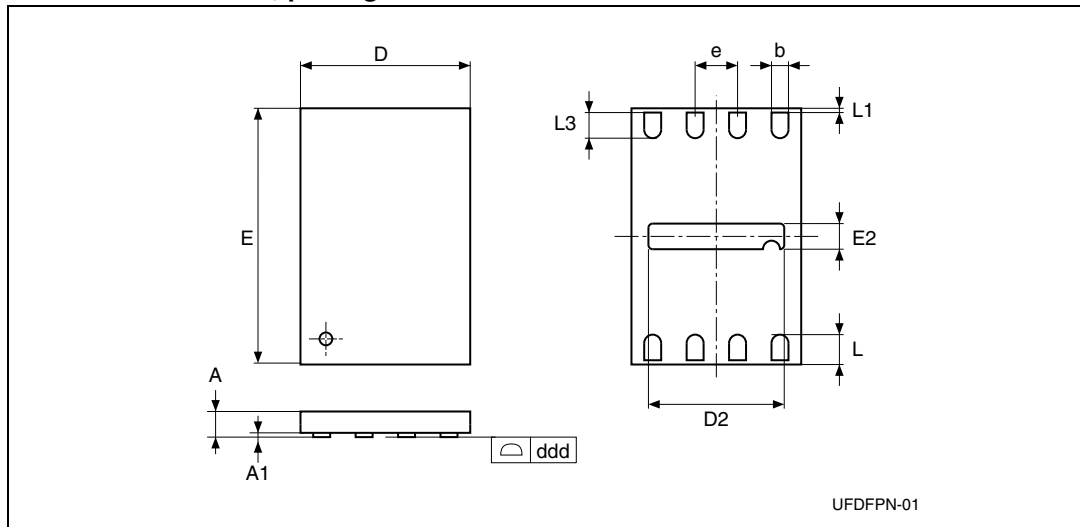
1. Drawing is not to scale.

**Table 28. SO8N – 8-lead plastic small outline, 150 mils body width, mechanical data**

| Symbol | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|--------|-------------|------|------|-----------------------|--------|--------|
|        | Typ         | Min  | Max  | Typ                   | Min    | Max    |
| A      |             |      | 1.75 |                       |        | 0.0689 |
| A1     |             | 0.1  | 0.25 |                       | 0.0039 | 0.0098 |
| A2     |             | 1.25 |      |                       | 0.0492 |        |
| b      |             | 0.28 | 0.48 |                       | 0.011  | 0.0189 |
| c      |             | 0.17 | 0.23 |                       | 0.0067 | 0.0091 |
| ccc    |             |      | 0.1  |                       |        | 0.0039 |
| D      | 4.9         | 4.8  | 5    | 0.1929                | 0.189  | 0.1969 |
| E      | 6           | 5.8  | 6.2  | 0.2362                | 0.2283 | 0.2441 |
| E1     | 3.9         | 3.8  | 4    | 0.1535                | 0.1496 | 0.1575 |
| e      | 1.27        | -    | -    | 0.05                  | -      | -      |
| h      |             | 0.25 | 0.5  |                       | 0.0098 | 0.0197 |
| k      |             | 0°   | 8°   |                       | 0°     | 8°     |
| L      |             | 0.4  | 1.27 |                       | 0.0157 | 0.05   |
| L1     | 1.04        |      |      | 0.0409                |        |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 19. UFDFPN8 (MLP8) 8-lead ultra thin fine pitch dual flat package no lead  
2 x 3 mm, package outline**

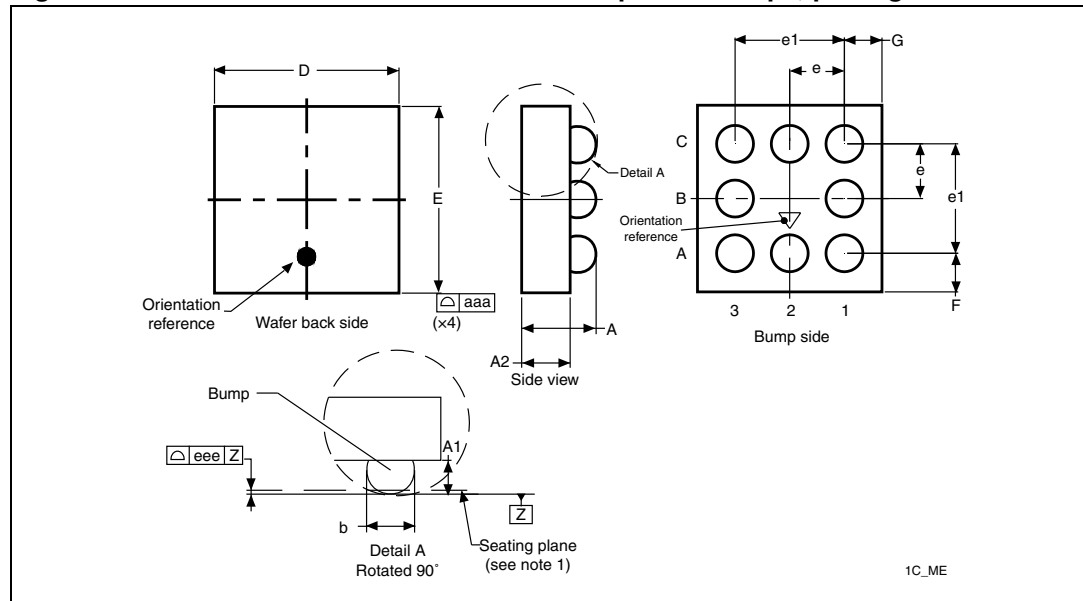


1. Drawing is not to scale.
2. The central pad (the area E2 by D2 in the above illustration) is internally pulled to  $V_{SS}$ . It must not be connected to any other voltage or signal line on the PCB, for example during the soldering process.

**Table 29. UFDFPN8 (MLP8) 8-lead ultra thin fine pitch dual flat package no lead  
2 x 3 mm, package mechanical data**

| Symbol             | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|--------------------|-------------|------|------|-----------------------|--------|--------|
|                    | Typ         | Min  | Max  | Typ                   | Min    | Max    |
| A                  | 0.55        | 0.45 | 0.6  | 0.0217                | 0.0177 | 0.0236 |
| A1                 | 0.02        | 0    | 0.05 | 0.0008                | 0      | 0.002  |
| b                  | 0.25        | 0.2  | 0.3  | 0.0098                | 0.0079 | 0.0118 |
| D                  | 2           | 1.9  | 2.1  | 0.0787                | 0.0748 | 0.0827 |
| D2                 | 1.6         | 1.5  | 1.7  | 0.063                 | 0.0591 | 0.0669 |
| E                  | 3           | 2.9  | 3.1  | 0.1181                | 0.1142 | 0.122  |
| E2                 | 0.2         | 0.1  | 0.3  | 0.0079                | 0.0039 | 0.0118 |
| e                  | 0.5         | -    | -    | 0.0197                | -      | -      |
| L                  | 0.45        | 0.4  | 0.5  | 0.0177                | 0.0157 | 0.0197 |
| L1                 |             |      | 0.15 |                       |        | 0.0059 |
| L3                 |             | 0.3  |      |                       | 0.0118 |        |
| ddd <sup>(2)</sup> | 0.08        |      |      | 0.08                  |        |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. Applied for exposed die paddle and terminals. Exclude embedding part of exposed die paddle from measuring.

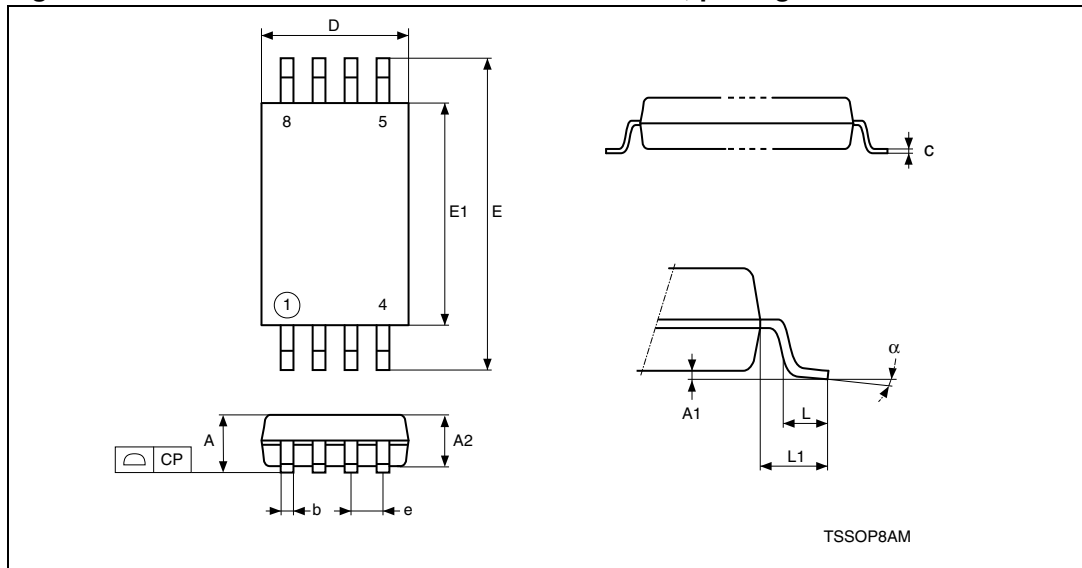
**Figure 20. WLCSP-R 1.350 x 1.365 mm 0.4 mm pitch 8 bumps, package outline**

1. Primary datum Z and seating plane are defined by the spherical crowns of the bump.
2. Drawing is not to scale.
3. Preliminary data.

**Table 30. WLCSP-R 1.350 x 1.365 mm 0.4 mm pitch 8 bumps, package mechanical data<sup>(1)</sup>**

| Symbol                        | millimeters |       |       | inches <sup>(2)</sup> |        |        |
|-------------------------------|-------------|-------|-------|-----------------------|--------|--------|
|                               | Typ         | Min   | Max   | Typ                   | Min    | Max    |
| A                             | 0.545       | 0.490 | 0.600 | 0.0193                | 0.0215 | 0.0236 |
| A1                            | 0.190       |       |       | 0.0075                |        |        |
| A2                            | 0.355       |       |       | 0.014                 |        |        |
| b <sup>(3)</sup>              | 0.270       | 0.240 | 0.300 | 0.0106                | 0.0094 | 0.0118 |
| D                             | 1.350       |       | 1.475 | 0.0531                |        | 0.0581 |
| E                             | 1.365       |       | 1.490 | 0.0537                |        | 0.0587 |
| e                             | 0.400       |       |       | 0.0157                |        |        |
| e1                            | 0.800       |       |       | 0.0315                |        |        |
| F                             | 0.282       |       |       | 0.0111                |        |        |
| G                             | 0.275       |       |       | 0.0108                |        |        |
| N (total number of terminals) | 8           |       |       | 8                     |        |        |
| aaa                           | 0.110       |       |       | 0.0043                |        |        |
| eee                           | 0.060       |       |       | 0.0024                |        |        |

1. Preliminary data.
2. Values in inches are converted from mm and rounded to 4 decimal digits.
3. Dimension is measured at the maximum bump diameter parallel to primary datum Z.

**Figure 21. TSSOP8 – 8-lead thin shrink small outline, package outline**

1. Drawing is not to scale.

**Table 31. TSSOP8 – 8-lead thin shrink small outline, package mechanical data**

| Symbol   | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|----------|-------------|------|------|-----------------------|--------|--------|
|          | Typ         | Min  | Max  | Typ                   | Min    | Max    |
| A        |             |      | 1.2  |                       |        | 0.0472 |
| A1       |             | 0.05 | 0.15 |                       | 0.002  | 0.0059 |
| A2       | 1           | 0.8  | 1.05 | 0.0394                | 0.0315 | 0.0413 |
| b        |             | 0.19 | 0.3  |                       | 0.0075 | 0.0118 |
| c        |             | 0.09 | 0.2  |                       | 0.0035 | 0.0079 |
| CP       |             |      | 0.1  |                       |        | 0.0039 |
| D        | 3           | 2.9  | 3.1  | 0.1181                | 0.1142 | 0.122  |
| e        | 0.65        | -    | -    | 0.0256                | -      | -      |
| E        | 6.4         | 6.2  | 6.6  | 0.252                 | 0.2441 | 0.2598 |
| E1       | 4.4         | 4.3  | 4.5  | 0.1732                | 0.1693 | 0.1772 |
| L        | 0.6         | 0.45 | 0.75 | 0.0236                | 0.0177 | 0.0295 |
| L1       | 1           |      |      | 0.0394                |        |        |
| $\alpha$ |             | 0°   | 8°   |                       | 0°     | 8°     |
| N        | 8           |      |      | 8                     |        |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

# 11 Part numbering

**Table 32. Ordering information scheme**

|                                                                         |        |   |   |    |   |   |   |    |
|-------------------------------------------------------------------------|--------|---|---|----|---|---|---|----|
| Example:                                                                | M95160 | – | W | MN | 6 | T | P | /S |
| <b>Device type</b>                                                      |        |   |   |    |   |   |   |    |
| M95 = SPI serial access EEPROM                                          |        |   |   |    |   |   |   |    |
| <b>Device function</b>                                                  |        |   |   |    |   |   |   |    |
| 160 = 16 Kbit (2048 x 8)                                                |        |   |   |    |   |   |   |    |
| 080 = 8 Kbit (1024 x 8)                                                 |        |   |   |    |   |   |   |    |
| <b>Operating voltage</b>                                                |        |   |   |    |   |   |   |    |
| blank = $V_{CC} = 4.5$ to $5.5$ V                                       |        |   |   |    |   |   |   |    |
| W = $V_{CC} = 2.5$ to $5.5$ V                                           |        |   |   |    |   |   |   |    |
| R = $V_{CC} = 1.8$ to $5.5$ V                                           |        |   |   |    |   |   |   |    |
| F = $V_{CC} = 1.7$ to $5.5$ V                                           |        |   |   |    |   |   |   |    |
| <b>Package</b>                                                          |        |   |   |    |   |   |   |    |
| MN = SO8 (150 mil width)                                                |        |   |   |    |   |   |   |    |
| DW = TSSOP8                                                             |        |   |   |    |   |   |   |    |
| MB = MLP8 (UFDFPN8)                                                     |        |   |   |    |   |   |   |    |
| CS = WLCSP <sup>(1)</sup>                                               |        |   |   |    |   |   |   |    |
| <b>Device grade</b>                                                     |        |   |   |    |   |   |   |    |
| 6 = Industrial temperature range, $-40$ to $85$ °C.                     |        |   |   |    |   |   |   |    |
| Device tested with standard test flow                                   |        |   |   |    |   |   |   |    |
| 3 = Device tested with high reliability certified flow <sup>(2)</sup> . |        |   |   |    |   |   |   |    |
| Automotive temperature range ( $-40$ to $125$ °C)                       |        |   |   |    |   |   |   |    |
| <b>Option</b>                                                           |        |   |   |    |   |   |   |    |
| blank = Standard packing                                                |        |   |   |    |   |   |   |    |
| T = Tape and reel packing                                               |        |   |   |    |   |   |   |    |
| <b>Plating technology</b>                                               |        |   |   |    |   |   |   |    |
| G or P = ECOPACK® (RoHS compliant)                                      |        |   |   |    |   |   |   |    |
| <b>Process<sup>(3)</sup></b>                                            |        |   |   |    |   |   |   |    |
| /G or /S = F6SP36%                                                      |        |   |   |    |   |   |   |    |

1. Preliminary data.
2. ST strongly recommends the use of the Automotive Grade devices for use in an automotive environment. The high reliability certified flow (HRCF) is described in the quality note QNEE9801. Please ask your nearest ST sales office for a copy.
3. The Process letter (/G or /S) applies only to Range 3 devices. For Range 6 devices, the process letters do not appear in the Ordering Information but only appear on the device package (marking) and on the shipment box. Please contact your nearest ST Sales Office. For more information on how to identify products by the Process Identification Letter, please refer to AN2043: Serial EEPROM Device Marking.

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.

**Table 33. Available M95160 products (package, voltage range, temperature grade)**

| Package           | M95160<br>4.5 V to 5.5 V | M95160-W<br>2.5 V to 5.5 V | M95160-R<br>1.8 V to 5.5 V | M95160-F<br>1.7 V to 5.5 V |
|-------------------|--------------------------|----------------------------|----------------------------|----------------------------|
| SO8 (MN)          | Range 6<br>Range3        | Range 6<br>Range3          | Range 6                    | NA <sup>(1)</sup>          |
| TSSOP (DW)        | NA <sup>(1)</sup>        | Range 6<br>Range3          | Range 6                    | Range 6                    |
| MLP 2 x 3 mm (MB) | NA <sup>(1)</sup>        | NA <sup>(1)</sup>          | Range 6                    | NA <sup>(1)</sup>          |
| WLCSP (CS)        | NA <sup>(1)</sup>        | NA <sup>(1)</sup>          | Range 6                    | Range 6                    |

1. NA = Not available

**Table 34. Available M95080 products (package, voltage range, temperature grade)**

| Package          | M95080<br>4.5 V to 5.5 V | M95080-W<br>2.5 V to 5.5 V | M95080-R<br>1.8 V to 5.5 V |
|------------------|--------------------------|----------------------------|----------------------------|
| SO8 (MN)         | Range 6<br>Range3        | Range 6<br>Range3          | Range 6                    |
| TSSOP (DW)       | NA <sup>(1)</sup>        | Range 6<br>Range3          | Range 6                    |
| MLP 2 x 3mm (MB) | NA <sup>(1)</sup>        | Range 6                    | Range 6                    |

1. NA = Not available

## 12 Revision history

**Table 35. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                |
|-------------|----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 19-Jul-2001 | 1.0      | Document written from previous M95640/320/160/080 datasheet                                                                                                                                                                                                                                                                                                                                                            |
| 06-Feb-2002 | 1.1      | Announcement made of planned upgrade to 10MHz clock for the 5V, –40 to 85°C, range                                                                                                                                                                                                                                                                                                                                     |
| 18-Oct-2002 | 1.2      | TSSOP8 (3x3mm body size, MSOP8) package added                                                                                                                                                                                                                                                                                                                                                                          |
| 04-Nov-2002 | 1.3      | New products, identified by the process letter W, added                                                                                                                                                                                                                                                                                                                                                                |
| 13-Nov-2002 | 1.4      | Correction to footnote in Ordering Information table                                                                                                                                                                                                                                                                                                                                                                   |
| 21-Nov-2003 | 2.0      | Table of contents, and Pb-free options added. $V_{IL}(\text{min})$ improved to –0.45V                                                                                                                                                                                                                                                                                                                                  |
| 08-Jun-2004 | 3.0      | MLP8 package added. Absolute Maximum Ratings for $V_{IO}(\text{min})$ and $V_{CC}(\text{min})$ improved. Soldering temperature information clarified for RoHS compliant devices. Device Grade 3 clarified, with reference to HRCF and automotive environments. Process identification letter “G” information added. SO8 narrow and TSSOP8 Package mechanical specifications updated.                                   |
| 07-Oct-2004 | 4.0      | Product List summary table added. AEC-Q100-002 compliance. tHHQX corrected to tHHQV.<br>10MHz, 5ms Write is now the present product. tCH+tCL<1/fC constraint clarified                                                                                                                                                                                                                                                 |
| 21-Sep-2005 | 5.0      | Added 20MHz and -S product information. Removed DIP package. Info on Pull-up resistors, VCC lines and Note 2. added to <a href="#">Figure 4.: Bus master and memory devices on the SPI bus. Device internal reset</a> paragraph clarified. Packages compliant with the JEDEC Std J-STD-020C. Process info updated in <a href="#">DC and AC parameters</a> and <a href="#">Table 32.: Ordering information scheme</a> . |

Table 35. Document revision history (continued)

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|-------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 24-May-2007 | 6        | <p>Document reformatted. Small text changes.</p> <p>TSSOP8 3 x 3 mm (DS) package removed, 1.65 V to 5.5 V operating voltage range removed (M95080-S and M95160-S removed).</p> <p><a href="#">Figure 4: Bus master and memory devices on the SPI bus</a> updated, note 2 removed and explanatory paragraph added (see <a href="#">Section 3: Connecting to the SPI bus</a>).</p> <p><a href="#">Section 2.7: VCC supply voltage</a> and <a href="#">Section 2.8: VSS ground</a> added.</p> <p>Power-up, Device Internal Reset and Power-down replaced by <a href="#">Section 4.1: Supply voltage (VCC)</a>.</p> <p>Command termination specified in <a href="#">Section 6.4: Write Status Register (WRSR)</a>.</p> <p>Blank process no longer available for M95160, M95080, M95160-W and M95080-W in the device grade 3 range.</p> <p>L, GB and SB processes no longer available for M95160 and M95080, in the device grade 6 range.</p> <p>L process no longer available for M95160-W and M95080-W in the device grade 6 range.</p> <p>I<sub>CC1</sub> value and test conditions modified in <a href="#">Table 19: DC characteristics (M95160-R and M95080-R)</a>.</p> <p>End timing line of t<sub>SHQZ</sub> modified in <a href="#">Figure 17: Serial output timing</a>.</p> <p>SO8N and UFDFPN8 package specifications updated. All packages are ECOPACK® compliant.</p> <p>Blank option removed below Plating technology and Note 2 modified in <a href="#">Table 32: Ordering information scheme</a>.</p> <p><a href="#">Table 33: Available M95160 products (package, voltage range, temperature grade)</a> and <a href="#">Table 34: Available M95080 products (package, voltage range, temperature grade)</a> added.</p> |
| 06-Mar-2008 | 7        | <p>Endurance modified <a href="#">on page 1</a>. Small text changes.</p> <p><a href="#">Section 4.1: Supply voltage (VCC) on page 12</a> modified.</p> <p><a href="#">Section 6.6: Write to Memory Array (WRITE) on page 23</a> modified.</p> <p><a href="#">Table 19: DC characteristics (M95160-R and M95080-R)</a> updated.</p> <p>Note removed below <a href="#">Table 24: AC characteristics (M95160-W and M95080-W, device grade 6) on page 35</a>.</p> <p>Inch values are calculated from millimeters and rounded to 4 decimal digits and UFDFPN package specifications updated (see <a href="#">Section 10: Package mechanical data on page 41</a>).</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| 26-Jan-2009 | 8        | <p>WLCSP (CS) package added (see <a href="#">Figure 20</a> and <a href="#">Table 30: WLCSP-R 1.350 x 1.365 mm 0.4 mm pitch 8 bumps, package mechanical data</a>).</p> <p>M95160-F part number added (delivered in WLCSP package and device grade 6 only).</p> <p><a href="#">Section 2.7: VCC supply voltage</a> and <a href="#">Section 6.4: Write Status Register (WRSR)</a> updated.</p> <p><a href="#">Table 27: AC characteristics (M95160-F)</a> added.</p> <p><a href="#">Figure 15: Serial input timing</a>, <a href="#">Figure 16: Hold timing</a> and <a href="#">Figure 17: Serial output timing</a> updated.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |

**Table 35. Document revision history (continued)**

| Date      | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
|-----------|----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 12-May-09 | 8        | <p><a href="#">Section 4.1.2: Device reset</a> updated.</p> <p>V<sub>RES</sub> added to DC characteristics tables <a href="#">15</a>, <a href="#">16</a>, <a href="#">17</a>, <a href="#">18</a>, <a href="#">19</a> and <a href="#">20</a>.</p> <p>Note added to <a href="#">Section 6.6: Write to Memory Array (WRITE)</a>.</p> <p><a href="#">Note 1</a> added to <a href="#">Table 19: DC characteristics (M95160-R and M95080-R)</a>.</p> <p>VIL and VOL modified in <a href="#">Table 20: DC characteristics (M95160-F)</a>.</p> <p><a href="#">Table 24: AC characteristics (M95160-W and M95080-W, device grade 6)</a> split into two tables: <a href="#">Table 24</a> for process GB or SB and <a href="#">Table 25</a> for process SA.</p> <p>M95160-F is now available in device grade 6 (<a href="#">Table 33: Available M95160 products (package, voltage range, temperature grade)</a> updated).</p> |

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